

PC SDRAM UNBUFFERED DIMM SPECIFICATION

REVISION 1.0

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Changes:

Revision 0.9 Oct., 1997

Changed example stackup spacing to 7-11-7-11-7 with 0.5 oz. Copper
Added Section for DIMM PCB and Assembly labeling requirements.
Changed topology diagram notes to allow additional vias.
Modified mechanicals to include heat sink notches.

Revision 1.0 Feb., 1998

Changed example stackup spacing to 7-10-9-10-7.
Removed specifications relating to 64Mbit / 2-bank SDRAM components.
Increased max overall thickness to 4.33mm to account for height of SOIC EEPROM.
Changed topology diagrams to allow additional vias.
Added note to mechanicals to indicate that heat sink notches are optional.
Increased max interval between vias connecting ground rings to 0.7".
Included specifications for outer layer clock trace lengths for x16 based designs.
Removed outer layer clock trace length placeholder for x8 based designs.
Modified mixed mode DIMM wiring diagrams and clock loading table to indicate that the higher density DRAMs must always be placed on the primary side of the DIMM.
Added information on Intel clock simulation assumptions to allow independent simulation of scenarios for which specific lengths are not specified.
Added configuration listings for 256MB and 512MB DIMMs based on 128Mbit and 256Mbit components respectively.
Removed the requirement that the vendor name and part number be provided in etch or silkscreen on the DIMM.

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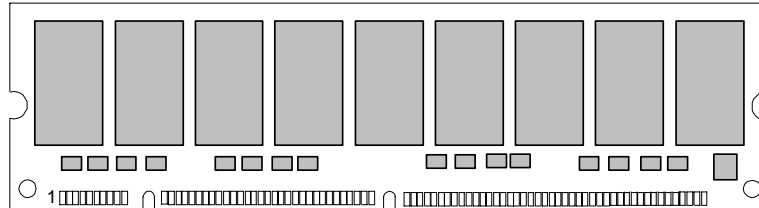
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1.0 Introduction

This specification defines the electrical and mechanical requirements for 168-pin, 3.3 volt, 64-bit and 72-bit wide, 4 clock, unbuffered Synchronous DRAM Dual In-Line Memory Modules (SDRAM DIMMs). These SDRAM DIMMs are intended for use as main memory installed on personal computer motherboards.



This specification largely follows the JEDEC defined 168-pin unbuffered SDRAM DIMM as of JEDEC committee meeting of December 1996.

This specification focuses on six layer double-sided assembly PCB designs. Other cost optimized designs may be possible; however, careful adherence to the contents of this spec as well as clock flight time and skew requirements on the DIMM is necessary. See section 6 below for information on clock flight time requirements for defining clock trace lengths.

Related Documents

Table 1: Related Documents

TITLE	REV
Intel PC SDRAM Specification	Current
Intel SDRAM SPD Data Structure Specification	Current

The related documents contain information that is critical to this specification. See the Intel Developer's web site at <http://developer.intel.com> for the latest revision of each spec.



DIMM Configurations

SDRAM DIMM configurations are defined in the following tables:

Table 2: SDRAM Non Mixed-Mode Module Configurations

Config #	DIMM Capacity	DIMM Organization	SDRAM density	SDRAM Organization	# of SDRAMs	# Rows of SDRAM	# Banks in SDRAM	# Address bits row/bank/col
1	8 MB	1M X 64	16 Mbit	1MX16	4	1	2	11/1/8
2	16 MB	2M X 64	16 Mbit	1MX16	8	2	2	11/1/8
3	16 MB	2M X 64	16 Mbit	2MX8	8	1	2	11/1/9
4	32 MB	4M X 64	16 Mbit	2MX8	16	2	2	11/1/9
5	16 MB	2M X 64	64 Mbit	2MX32	2	1	4	11/2/8
6	32 MB	4M X 64	64 Mbit	2MX32	4	2	4	11/2/8
7	32 MB	4M X 64	64 Mbit	4MX16	4	1	4	12/2/8
8	64 MB	8M X 64	64 Mbit	4MX16	8	2	4	12/2/8
9	64 MB	8M X 64	64 Mbit	8MX8	8	1	4	12/2/9
10	128 MB	16M X 64	64 Mbit	8MX8	16	2	4	12/2/9
11	16 MB	2M X 72	16 Mbit	2MX8	9	1	2	11/1/9
12	32 MB	4M X 72	16 Mbit	2MX8	18	2	2	11/1/9
13	64 MB	8M X 72	64 Mbit	8MX8	9	1	4	12/2/9
14	128 MB	16M X 72	64 Mbit	8MX8	18	2	4	12/2/9
15	8 MB	1M X 72	16 Mbit	1MX16	5	1	2	11/1/8
16	16 MB	2M X 72	16 Mbit	1MX16	10	2	2	11/1/8
17	32 MB	4M X 72	64 Mbit	4MX16	5	1	4	12/2/8
18	64 MB	8M X 72	64 Mbit	4MX16	10	2	4	12/2/8
19	256 MB	32M X 64	128 Mbit	16MX8	16	2	4	12/2/10
20	256 MB	32M X 72	128 Mbit	16MX8	18	2	4	12/2/10
21	512 MB	64M X 64	256 Mbit	32MX8	16	2	4	13/2/10
22	512 MB	64M X 72	256 Mbit	32MX8	18	2	4	13/2/10

Note 1: Modules constructed using x 4 bit SDRAMs are not supported (due to loading on select signals).

Note 2: Modules constructed using x 32 bit SDRAMs are still under investigation. Additional information will be released when it becomes available.

Table 3: SDRAM Mixed-Mode Module Configurations

Config #	DIMM Capacity	DIMM Organization	SDRAM density	SDRAM Organization	# of SDRAMs	# of Rows of SDRAM	Banks in SDRAM	# Address bits row/bank/col
1	24 MB	2M X 64 + 1M X 64	16 Mbit	2MX8	8	2	2	11/1/9
			16 Mbit	1MX16	4		2	11/1/8
2	48 MB	4M X 64 + 2M X 64	64 Mbit	4MX16	4	2	4	12/2/8
			16 Mbit	2MX8	8		2	11/1/9
3	24 MB	2M X 72 + 1M X72	16 Mbit	2MX8	9	2	2	11/1/9
			16 Mbit	1MX16	5		2	11/1/8
4	48 MB	4M X 72 + 2M X72	64 Mbit	4MX16	5	2	4	12/2/8
			16 Mbit	2MX8	9		2	11/1/9
5	96 MB	8M X 72 + 4M X 72	64 Mbit	8MX8	9	2	4	12/2/9
			64 Mbit	4MX16	5		4	12/2/8

Note: Modules constructed using x 4 bit SDRAMs are not supported (due to loading on select signals).

Note: Modules constructed using mixed configurations of x8 and x16 SDRAMs are still under investigation. Additional information will be released when it becomes available.

Design Stuffing Options

For the purpose of minimizing the total number of card designs that need to be generated, most Intel reference designs are being done double-sided in 6 layers and using this specification with the intent that these PCB designs will also work for single sided population and with or without stuffing the ECC devices. Therefore, there will be one card each designed for non-mixed mode configuration sets (1,2,15,16) (7,8,17,18) (3,4,11,12) (9,10,13,14). DIMM designs generated outside of Intel using the DIMM specification may opt not to do the same if cost or other considerations make it undesirable.

Distinction between “banks”

This document refers to two types of “banks”. One type relates to the banks of memory internal to the SDRAM component (two or four). The other type relates to the banks of SDRAM on a DIMM, also referred to as “rows”. The number of rows is the number of sets of SDRAMs on the DIMM that collectively make up 64 or 72 bits wide of data. When reading this document, please be aware of this distinction.

2.0 Environmental Requirements

The SDRAM DIMM shall be designed to operate within a personal computer cabinet in an office environment with limited capacity for heating and air conditioning. The temperature and humidity limits are listed below.

Table 4: DIMM Temperature, Humidity & Barometric Pressure Requirements

Operating Temperature	0 °C to +65 °C ambient
Operating Humidity	10% to 90% relative humidity
Storage Temperature	-50 °C to + 100 °C
Storage Humidity	5% to 95% without condensation
Barometric Pressure (operating & storage)	105K - 69K Pascal (up to 9,850 ft.)

Safety - UL Rating

Printed circuit board to have a flammability rating of 94V-O Markings to include UL tractability requirements per *UL Recognized Component Directory*.

3.0 Mechanical Design

The following table and mechanical drawings give the specific dimensions and tolerances for a 168-pin DIMM.

Table 5: DIMM Dimensions and Tolerances

SYMBOL	DEFINITION	MIN	NOM	MAX	NOTES
A	Overall module height measured from Datum -B-.	25.27 mm		38.23 mm	Range is 25.4 mm (1.0") to 38.10 mm. (1.5")
A1	The distance from Datum -B- to the centerline of the PWB alignment holes.	3.00 mm BASIC			These holes are not used by the next level of assembly. The dimensions are supplied for information only. If the holes are used in manufacturing they should be tightly toleranced. The recommended positional tolerance is 0.10 mm.
A2	The distance from Datum -B- to the centerline of the latch holes.	17.80 mm BASIC			
A4	The distance from Datum -B- to the lower edge of the Component Area on the front side of the PWB.	4.00 mm			
A5	The distance from Datum -B- to the lower edge of the Component Area on the back side of the PWB.	4.00 mm			
A6	The distance from Datum -B- to the leading edge of the contact.	0.05 mm		0.35 mm	The minimum distance prevents contact edge burrs.
A7	The distance from the top of the module (DATUM B + height A) to the centerline of the top heatsink notch arc.		4.45mm BASIC		
A8	The distance from the top of the module (DATUM B + height A) to the centerline of the bottom heatsink notch arc.		8.25mm	11.43mm	
b	The width of the plated input/output contact measured at the lateral midpoint of the contact.	0.95 mm	1.00 mm	1.05 mm	
D1	The overall length of the PWB.	133.22 mm	133.37 mm	133.52 mm	
D2	The longitudinal distance between the PWB machining alignment hole centers.	126.20 mm	127.35	128.50 mm	These holes are optional and may or may not be present. If they are present, they must be located as defined.

Table 6: DIMM Dimensions and Tolerances (continued)

SYMBOL	DEFINITION	MIN	NOM	MAX	NOTES
e	The pitch or distance between centerlines of the contacts	1.27 mm BASIC			
e1	The distance between the centerlines of Contact 1 and 84.		115.57 mm		
e2	The distance between the centerlines of Contact 85 and 168.		115.57 mm		
e3	The distance between the centerlines of Contact 1 and the contact located at the immediate left of the left key zone when viewing contact 1 side.		11.43 mm		The distance between the centerlines of contact 1 and 10.
e4	The distance between the centerlines of the contact at the immediate right of the left key zone and the contact at the immediate left of the center key zone when viewing contact 1 side.		36.83 mm		The distance between the centerlines of contact 11 and 40.
e5	The distance between the centerlines of the contact located at the immediate right of the center key zone and contact 84.		54.61 mm		The distance between the centerlines of contact 41 and 84.
H	The diameter of the PWB machined alignment holes.	2.90 mm	3.00 mm	3.10 mm	The machined alignment holes are optional.
L	The distance from Datum -B- to the top edge of the plated contact.	2.30 mm	2.50 mm	2.70 mm	
N	The total number of contacts.		168		
T	The thickness of the PCB including the contact metalization and plating.	1.17 mm	1.27 mm	1.37 mm	
T1	The overall thickness of the PWB with the components mounted. The overall thickness is measured from the highest component on the front side to the highest component on the backside.			4.33 mm	
aaa	The positional tolerance for the overall body length D1.	aaa = 0.15 mm @ Maximum Material Condition			
bbb	The straightness tolerance for the card thickness including the metalized contacts. This callout applies to the zone defined by A4, A5 and D1.		0.40 mm		bbb = 0.3% x D1 rounded to a two decimal place hard metric value.
ccc	The positional tolerance for the pattern of contacts with regard to primary Datum -A-.	ccc = 0.10 mm @ Least Material Condition			
ddd	The positional tolerance for the individual contact width b with regard to the theoretical centerline of the contact defined by basic dimension e.	ddd = 0.05 mm @ Least Material Condition			

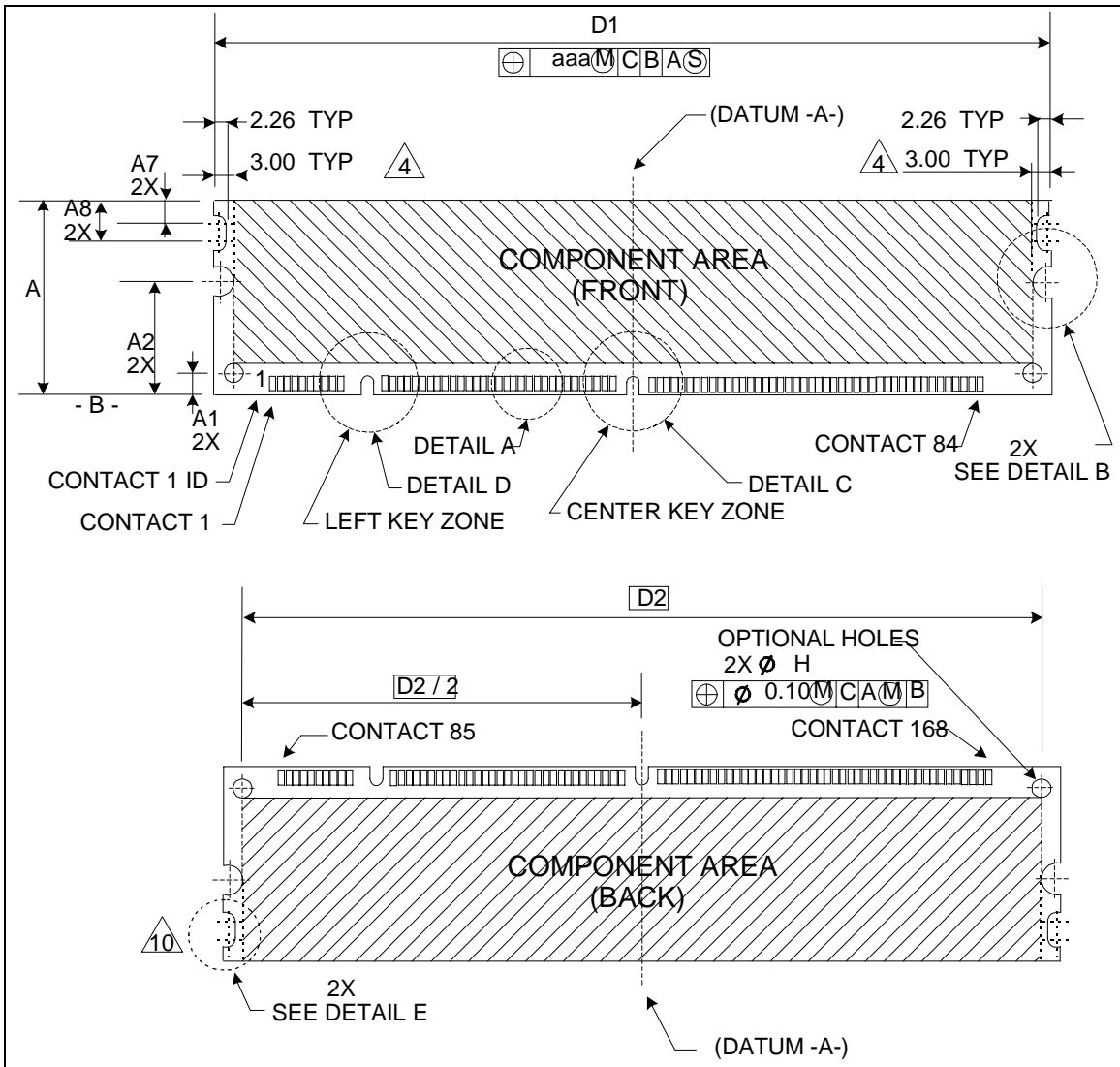


Figure 1: DIMM Mechanical Drawing (1 of 5)

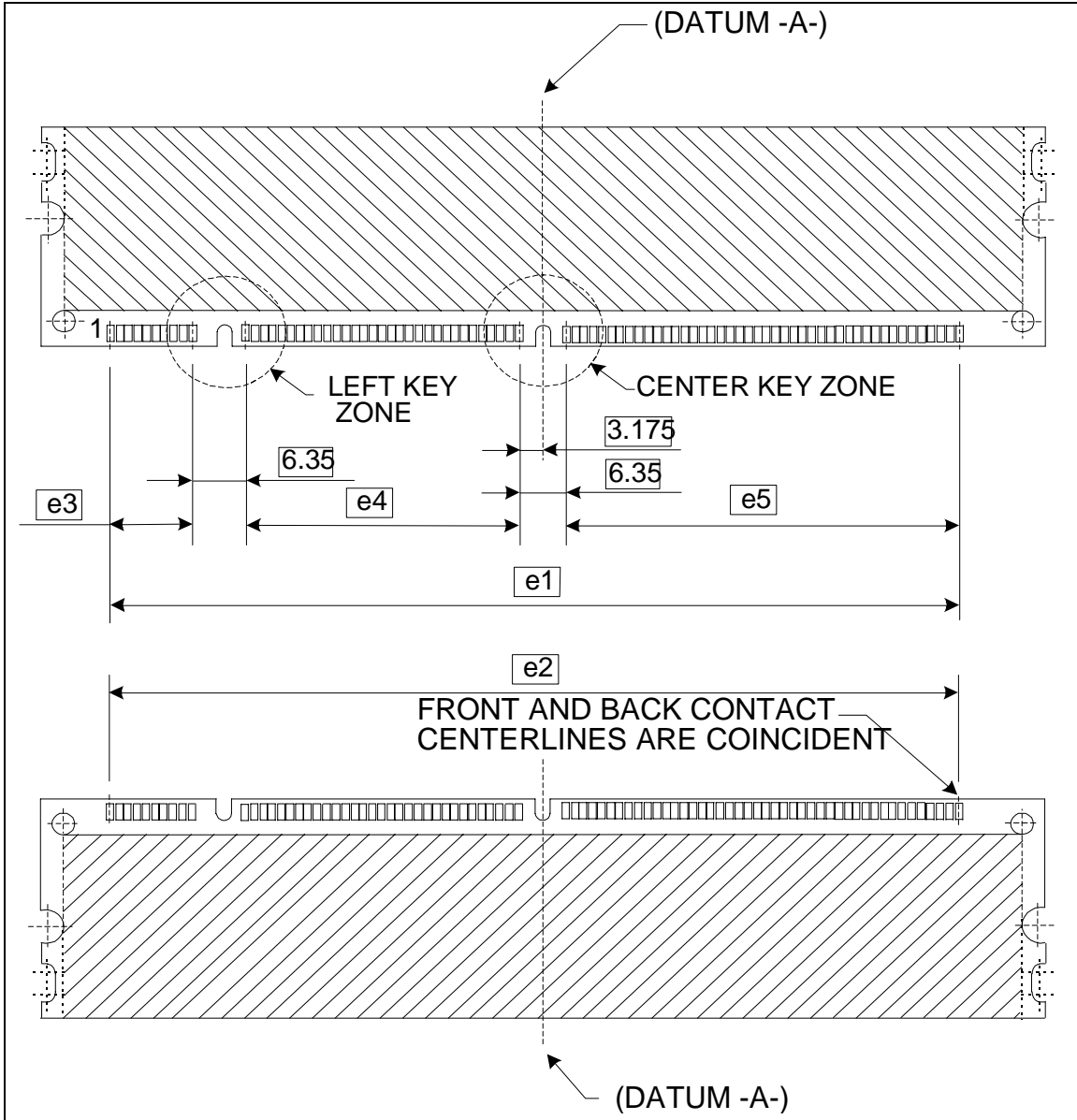


Figure 2: DIMM Mechanical Drawing (2 of 5)

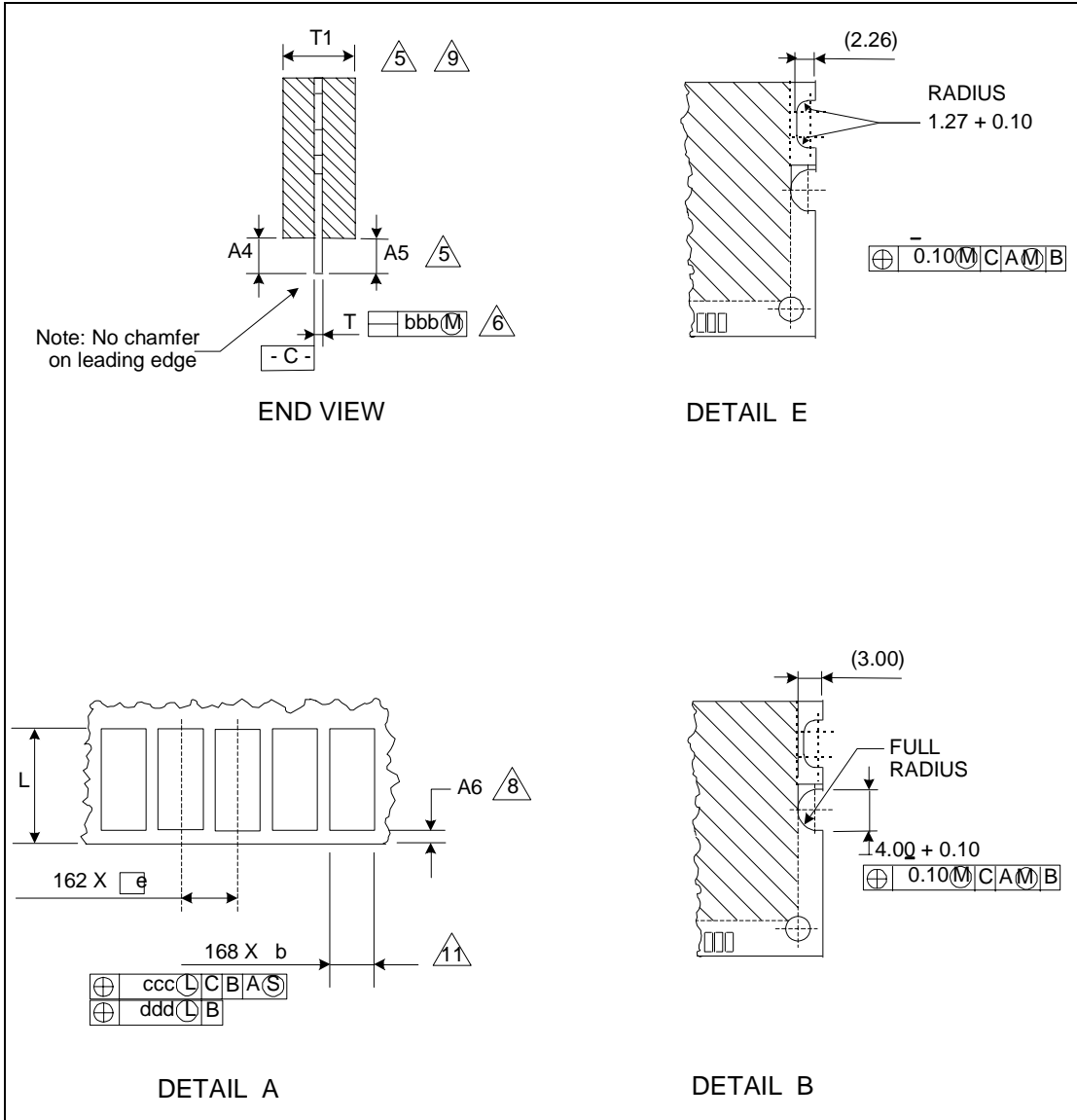


Figure 3: DIMM Mechanical Drawing (3 of 5)

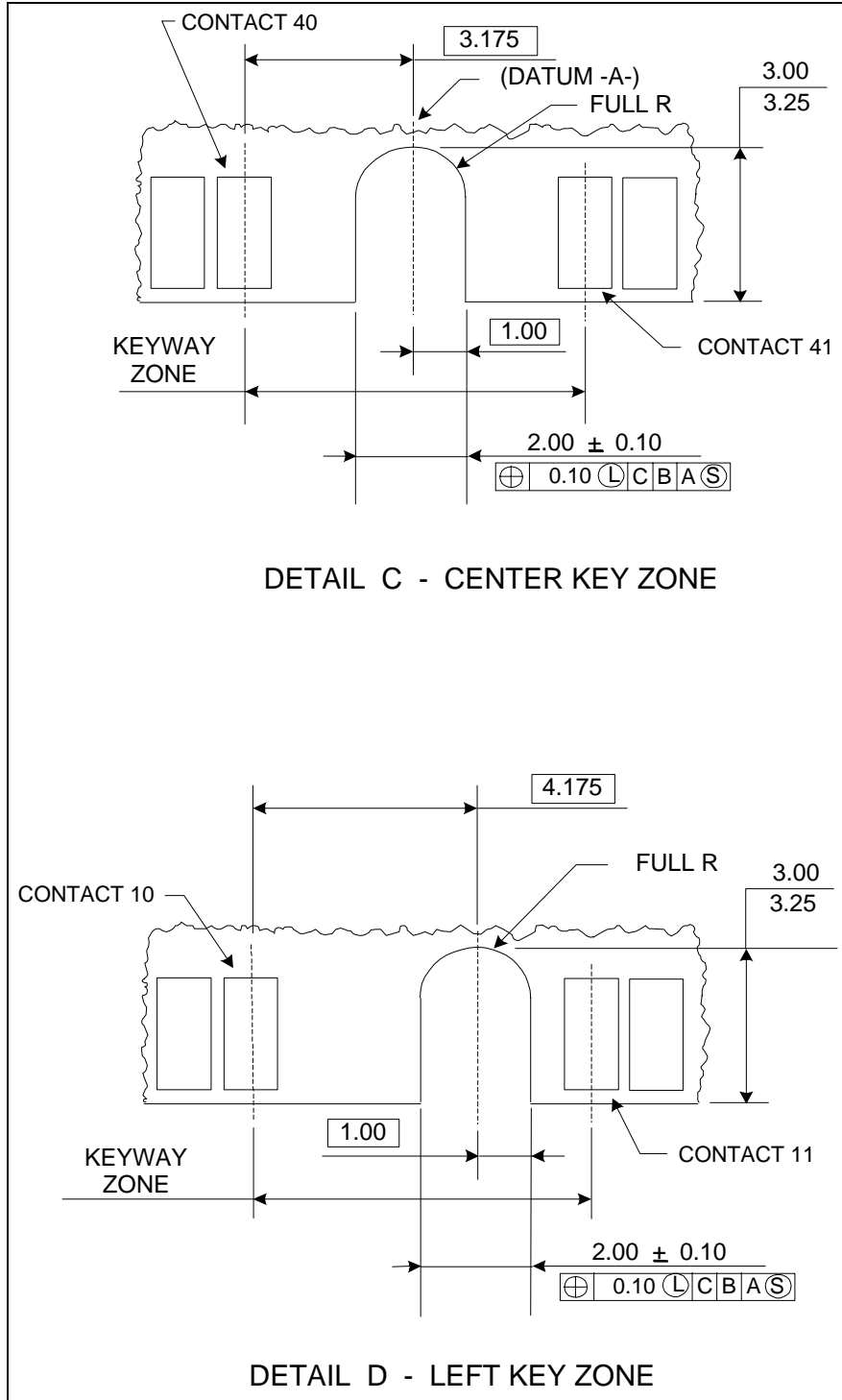


Figure 4: DIMM Mechanical Drawing (4 of 5)

NOTES

- 1 ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M-1994.
- 2 TOLERANCES ON ALL DIMENSIONS +/- 0.13 UNLESS OTHERWISE SPECIFIED.
- 3 ALL DIMENSIONS ARE IN MILLIMETERS.
- 4 3.00 mm TYPICAL APPLIES TO BOTH 4.00 mm WIDE NOTCH LENGTH AND COMPONENT KEEPOUT AREA.
- 5 DIMENSION APPLICABLE WHEN COMPONENTS MOUNTED ON BOTH SIDES.
- 6 CARD THICKNESS APPLIES ACROSS THE CONTACTS AND INCLUDES PLATING AND/OR METALIZATION. STRAIGHTNESS CALLOUT APPLIES TO ZONE DEFINED BY A4, A5, AND D1.
- 7 N IS THE TOTAL NUMBER OF CIRCUIT CONTACTS (PINS, LEADS, TABS OR PADS).
- 8 LEADING EDGE OF CONTACT ZONE SHALL BE FREE OF BURRS AND EXTERNAL TIE BARS.
- 9 THE MAXIMUM THICKNESS SHALL NOT EXCEED 4.33 mm.
- 10 HEATSINK NOTCHES ARE OPTIONAL. DIMENSIONS ARE PROVIDED FOR REFERENCE IN CASE THEY ARE DESIRED.

APPLICATION NOTES:

- 11 PLATING FOR CONTACT PADS: GOLD PLATING 0.75 MICROMETER MINIMUM OVER NI PLATING 2 MICROMETERS MINIMUM.
- 12 FOR OPTIMUM PERFORMANCE, IT IS RECOMMENDED THAT THE TIEBAR BE OFFSET FROM THE CENTERLINE OF THE PAD. ALSO, THE TIEBAR MAY BE AN INTERNAL LAYER, SO THE REMNANT CANNOT CAUSE CONTACT DAMAGE.

Figure 5: DIMM Mechanical Drawing (5 of 5)**Explanation of DIMM Keying**

All DIMMs generated from this spec should have two notches cut into the edge connection that convey information on the voltage of the DIMM and whether it is buffered or unbuffered. One notch should be positioned between DIMM pins 10 and 11 and should be closer in proximity to pin 11. This signifies that the DIMM is Unbuffered SDRAM/DRAM. The other notch should be positioned between DIMM pins 40 and 41 and should be centered between the two pins. This signifies that the DIMM operates using a V_{ddq} voltage of 3.3 Volts. Please see the mechanical drawings above for exact dimensions and placement of these notches.

4.0 Module Pinout

The following table provides the 168-pin 64-bit and 72-bit unbuffered DIMM module connector pinouts. Note that the eight error detection and correction bits CB(0:7) are actually NC for the 64-bit pinout.

Table 7: SDRAM DIMM pinout

Pin#	Signal Name	Pin#	Signal Name	Pin#	Signal Name	Pin#	Signal Name
1	Vss	43	Vss	85	Vss	127	Vss
2	DQ0	44	NC	86	DQ32	128	CKE0
3	DQ1	45	/S2	87	DQ33	129	/S3
4	DQ2	46	DQMB2	88	DQ34	130	DQMB6
5	DQ3	47	DQMB3	89	DQ35	131	DQMB7
6	Vdd	48	NC	90	Vdd	132	A13
7	DQ4	49	Vdd	91	DQ36	133	Vdd
8	DQ5	50	NC	92	DQ37	134	NC
9	DQ6	51	NC	93	DQ38	135	NC
10	DQ7	52	CB2	94	DQ39	136	CB6
11	DQ8	53	CB3	95	DQ40	137	CB7
12	Vss	54	Vss	96	Vss	138	Vss
13	DQ9	55	DQ16	97	DQ41	139	DQ48
14	DQ10	56	DQ17	98	DQ42	140	DQ49
15	DQ11	57	DQ18	99	DQ43	141	DQ50
16	DQ12	58	DQ19	100	DQ44	142	DQ51
17	DQ13	59	Vdd	101	DQ45	143	Vdd
18	Vdd	60	DQ20	102	Vdd	144	DQ52
19	DQ14	61	NC	103	DQ46	145	NC
20	DQ15	62	NC	104	DQ47	146	NC
21	CB0	63	CKE1	105	CB4	147	NC
22	CB1	64	Vss	106	CB5	148	Vss
23	Vss	65	DQ21	107	Vss	149	DQ53
24	NC	66	DQ22	108	NC	150	DQ54
25	NC	67	DQ23	109	NC	151	DQ55
26	Vdd	68	Vss	110	Vdd	152	Vss
27	/WE0	69	DQ24	111	/CAS	153	DQ56
28	DQMB0	70	DQ25	112	DQMB4	154	DQ57
29	DQMB1	71	DQ26	113	DQMB5	155	DQ58
30	/S0	72	DQ27	114	/S1	156	DQ59
31	NC	73	Vdd	115	/RAS	157	Vdd
32	Vss	74	DQ28	116	Vss	158	DQ60
33	A0	75	DQ29	117	A1	159	DQ61
34	A2	76	DQ30	118	A3	160	DQ62
35	A4	77	DQ31	119	A5	161	DQ63
36	A6	78	Vss	120	A7	162	Vss
37	A8	79	CK2	121	A9	163	CK3
38	A10 (AP)	80	NC	122	BA0	164	NC
39	BA1	81	WP	123	A11	165	SA0
40	Vdd	82	SDA	124	Vdd	166	SA1
41	Vdd	83	SCL	125	CK1	167	SA2
42	CK0	84	Vdd	126	A12	168	Vdd

Note: NC = Not Connected

5.0 SDRAM DIMM Block Diagrams

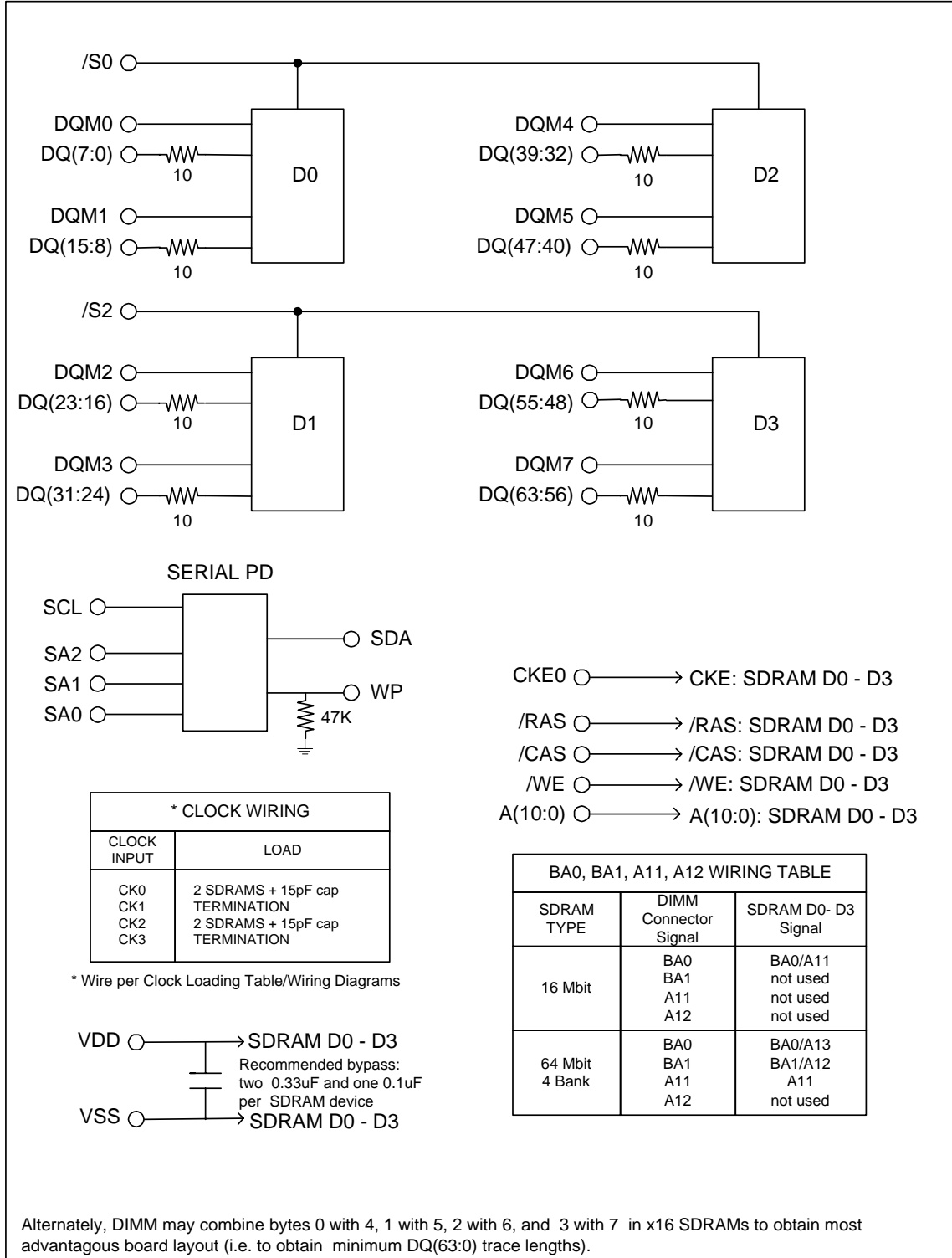


Figure 6: 64-bit non-ECC DIMM Block Diagram (1 Row, x16 SDRAMs)

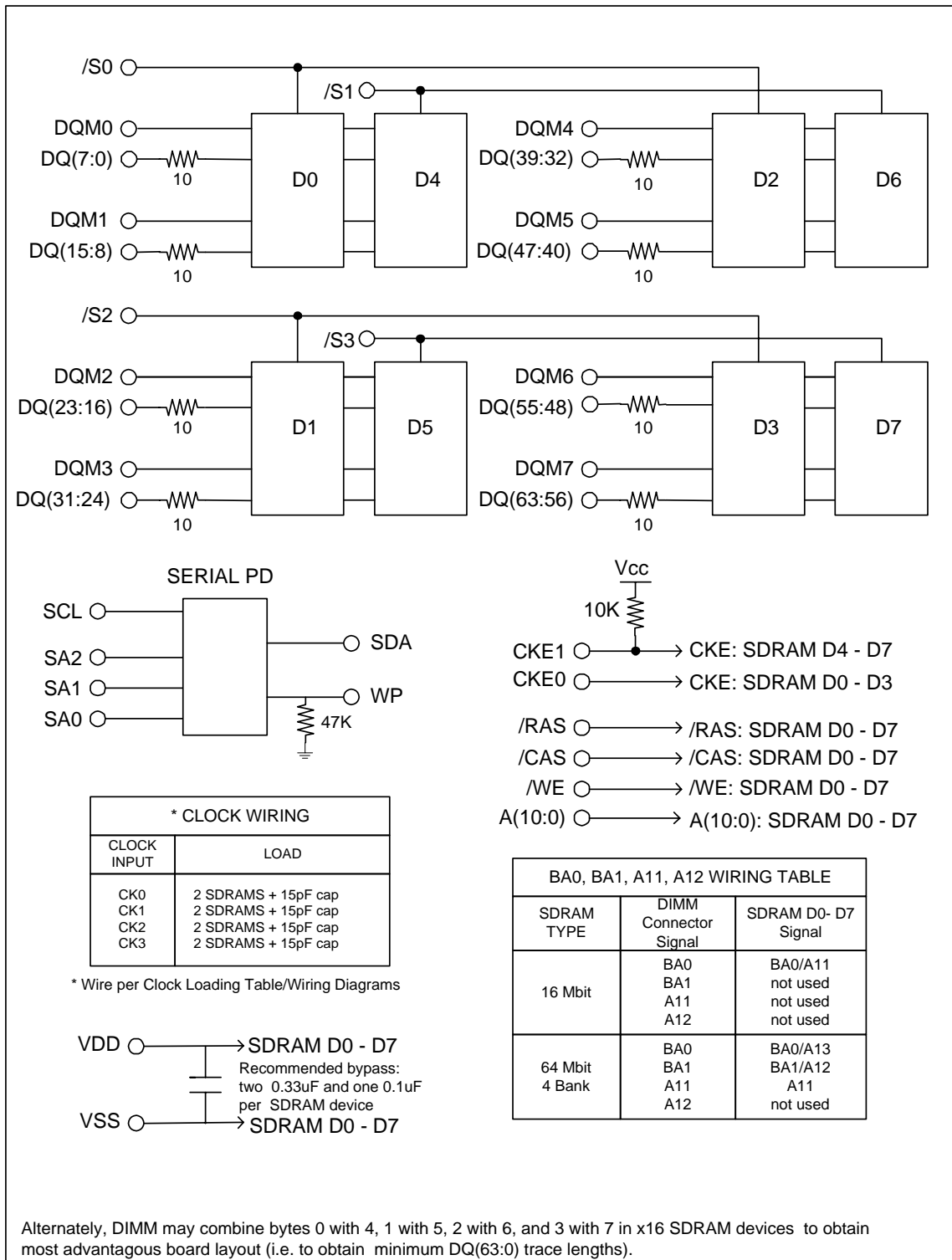


Figure 7: 64-bit non-ECC DIMM Block Diagram (2 Rows, x16 SDRAMs)

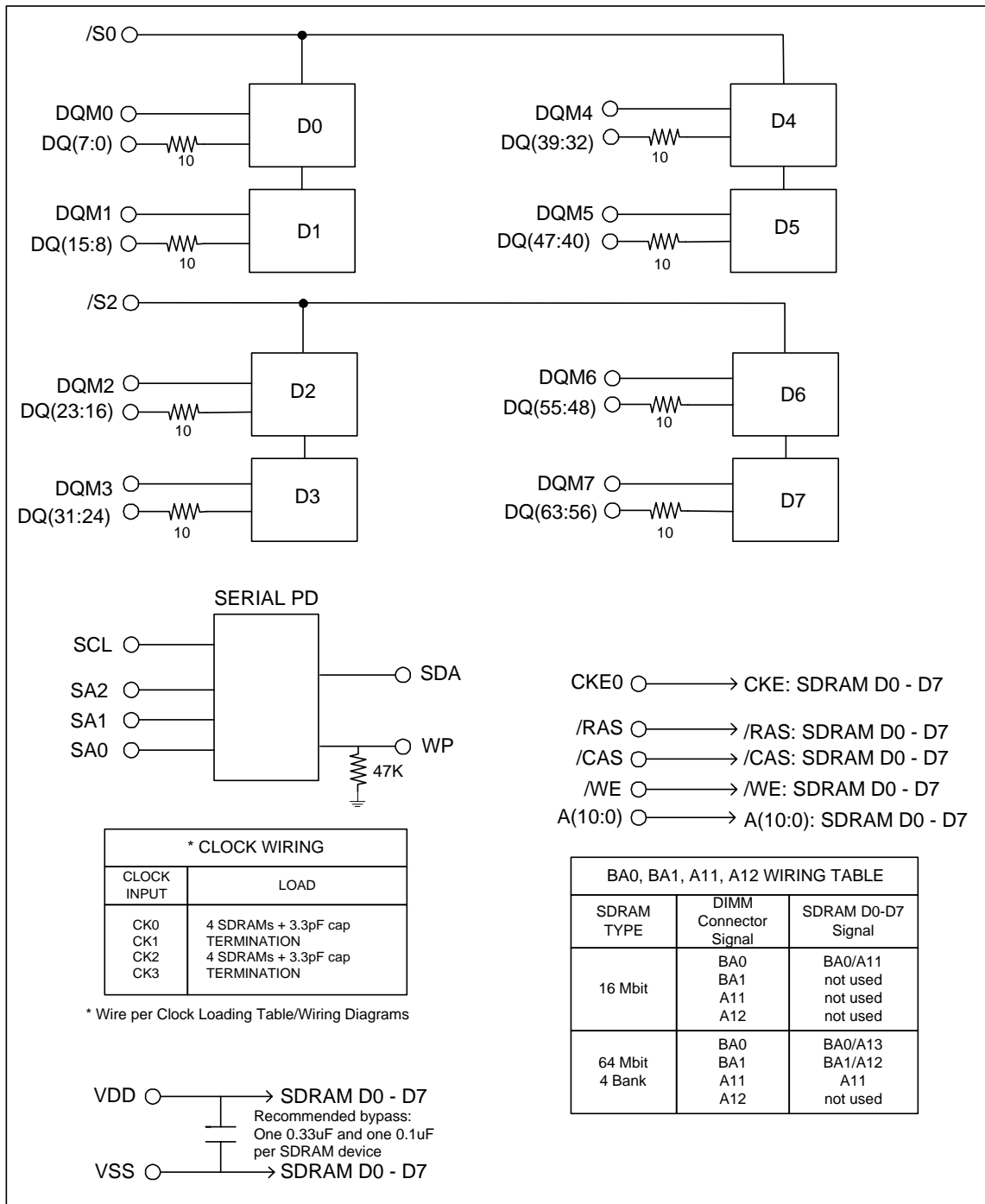


Figure 8: 64 bit non-ECC DIMM Block Diagram (1 Row x8 SDRAMs)

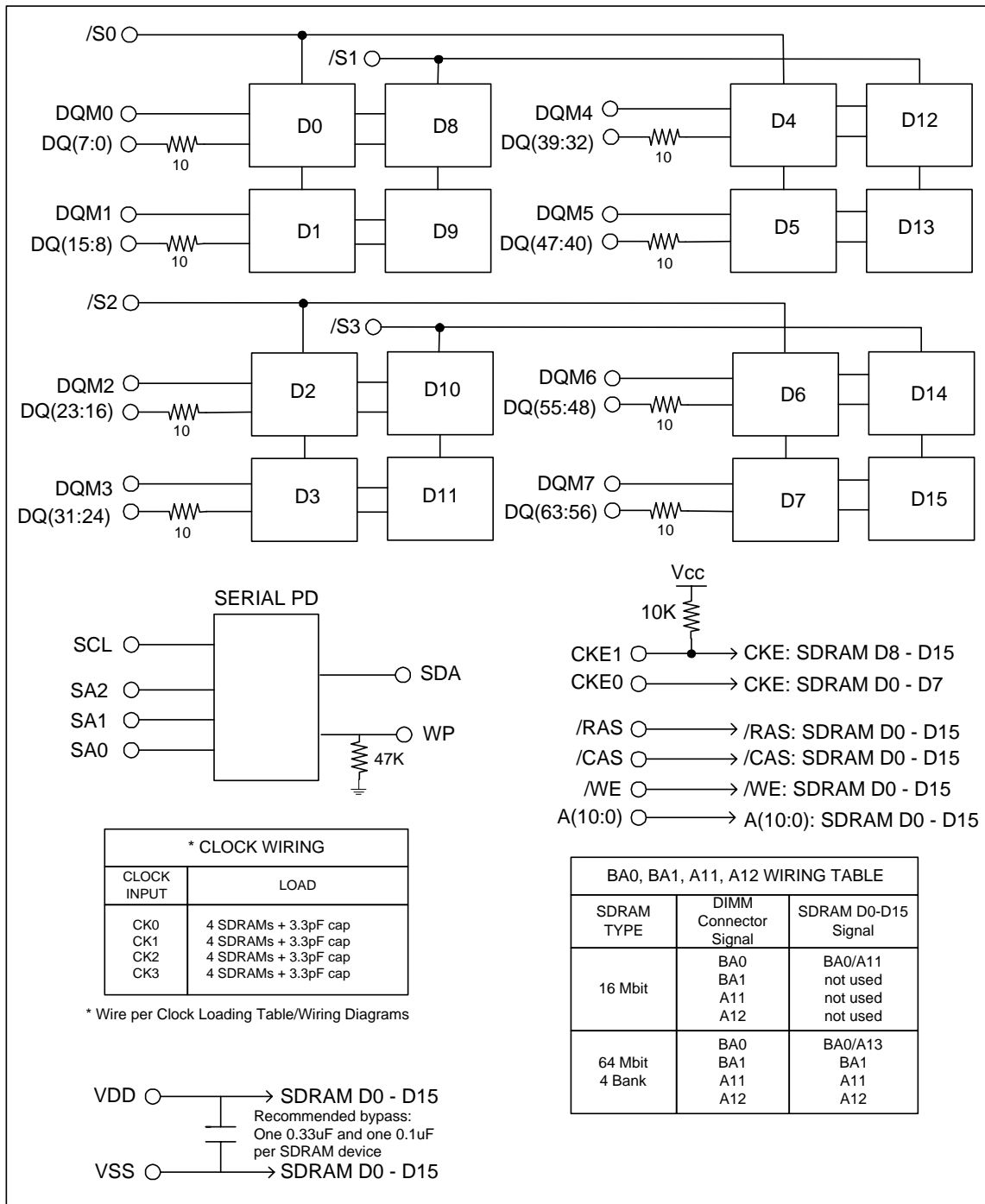


Figure 9: 64-bit non-ECC DIMM Block Diagram (2 Rows x8 SDRAMs)

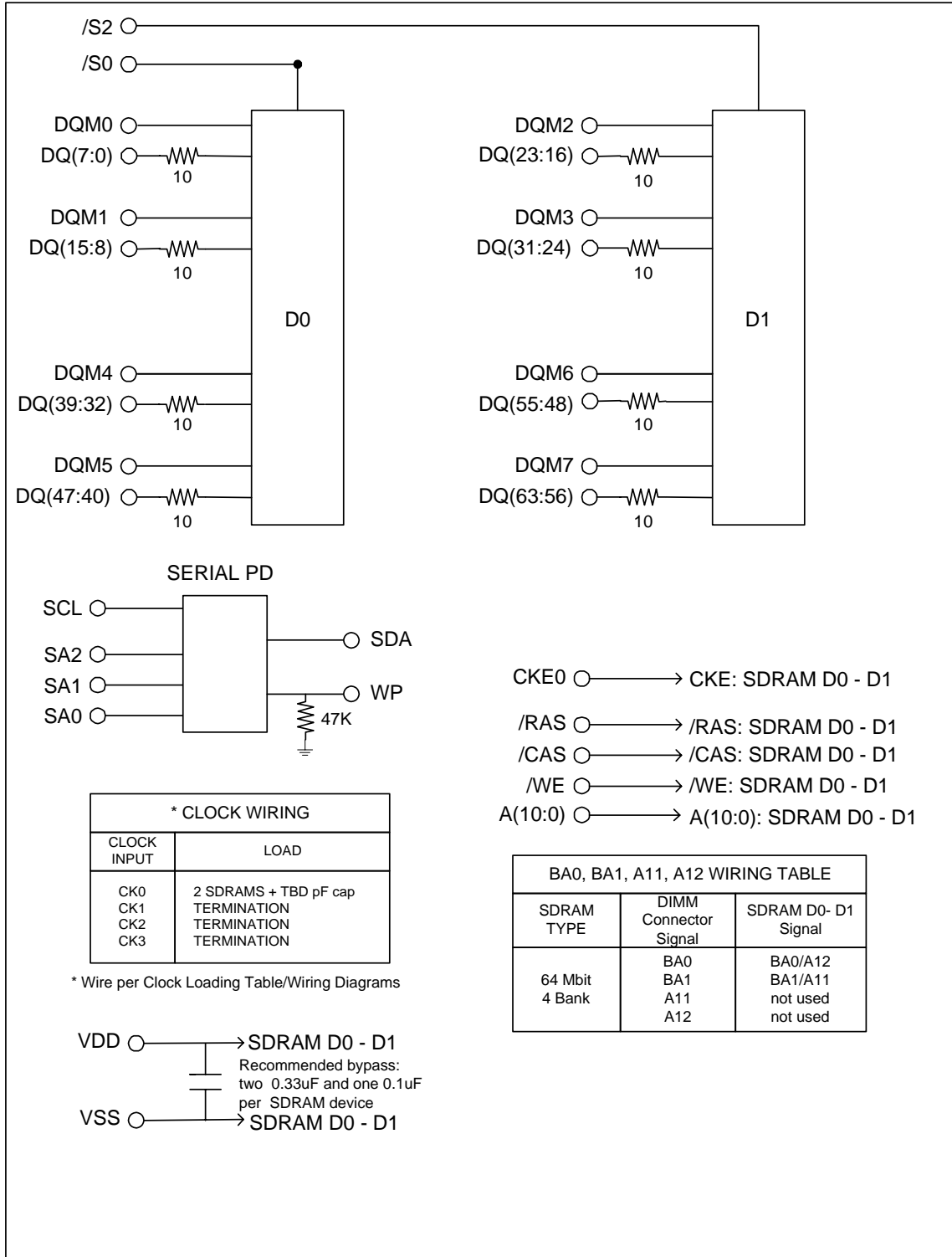


Figure 10: 64 bit non-ECC Block Diagram (1 Row x 32 SDRAMs)

Note: Modules constructed using x 32 bit SDRAMs are still under investigation. Additional information will be released when it becomes available.

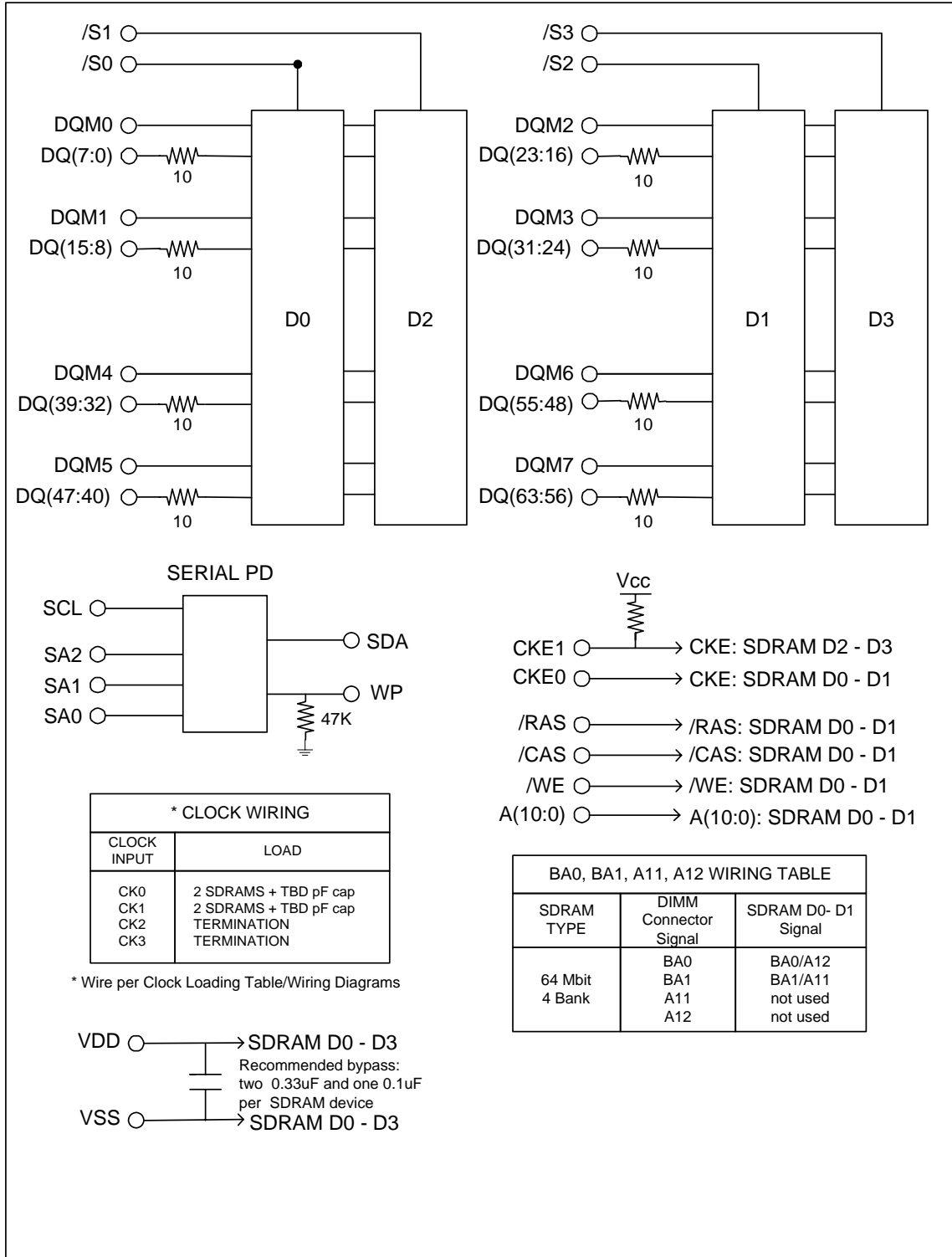


Figure 11: 64-bit non-ECC Block Diagram (2 Rows x32 SDRAMs)

Note: Modules constructed using x 32 bit SDRAMs are still under investigation. Additional information will be released when it becomes available.

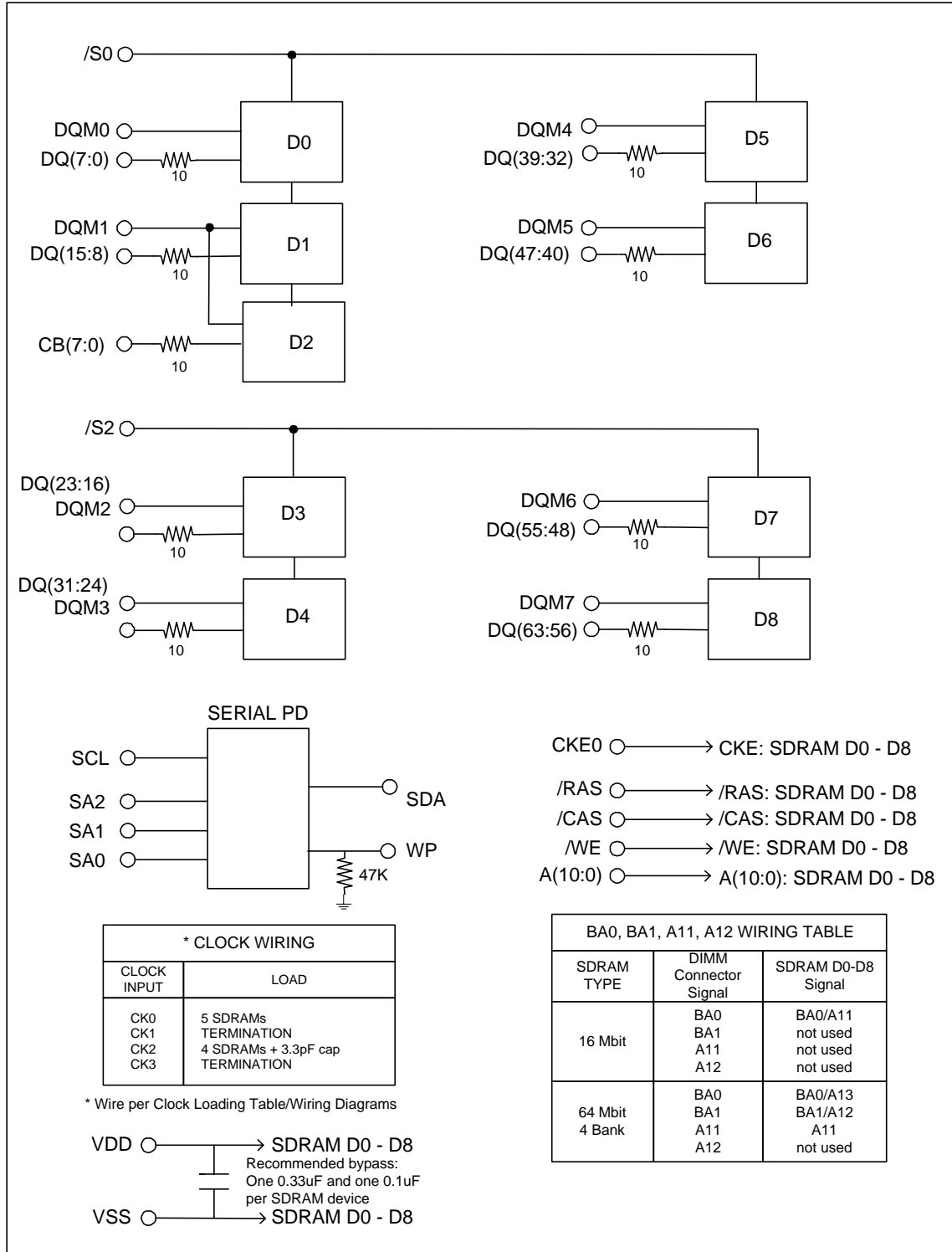


Figure 12: 72-Bit ECC SDRAM DIMM Block Diagram (1 row x8 SDRAMs)

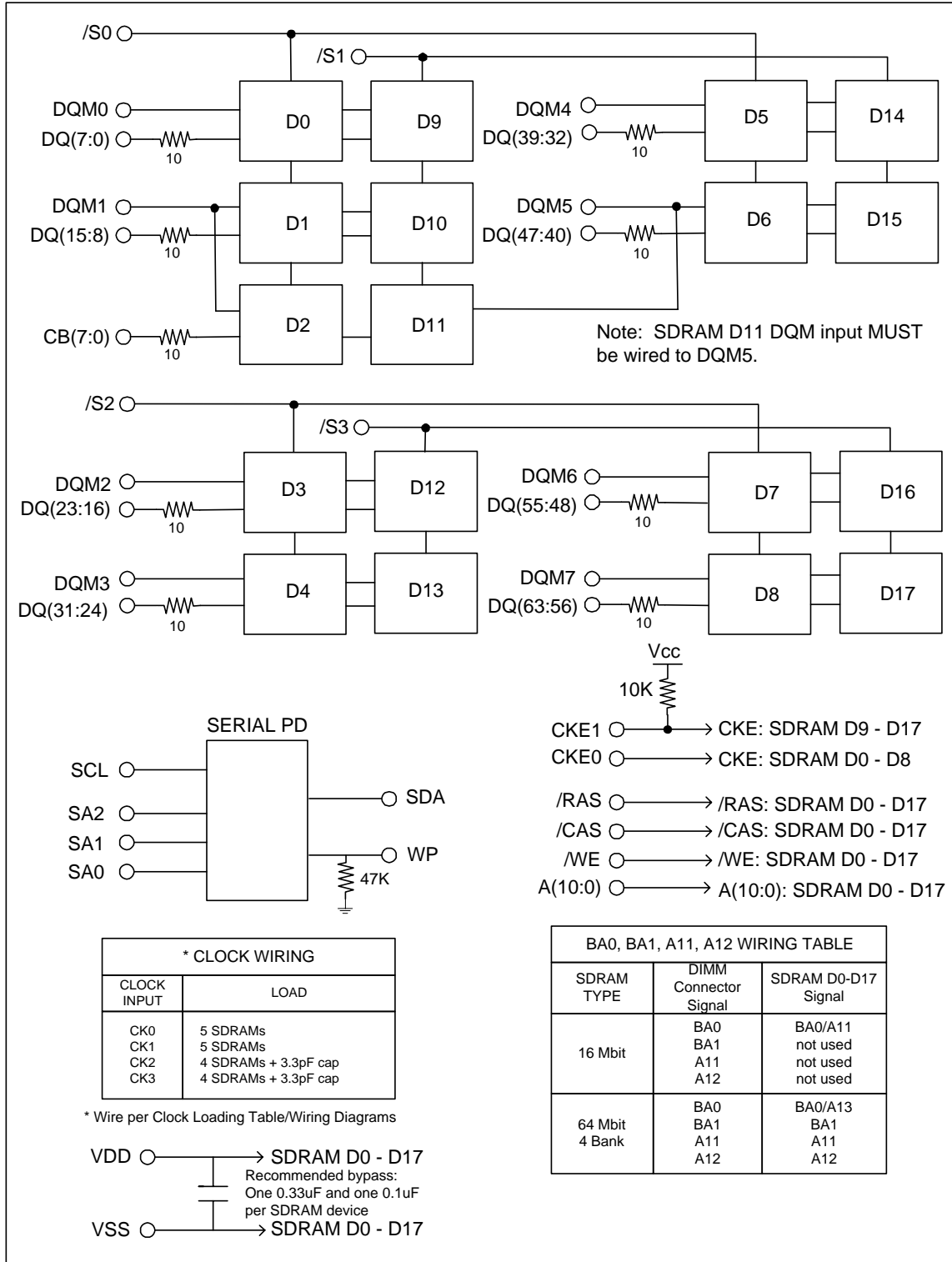


Figure 13: 72-Bit ECC SDRAM DIMM Block Diagram (2 rows x 8 SDRAMs)

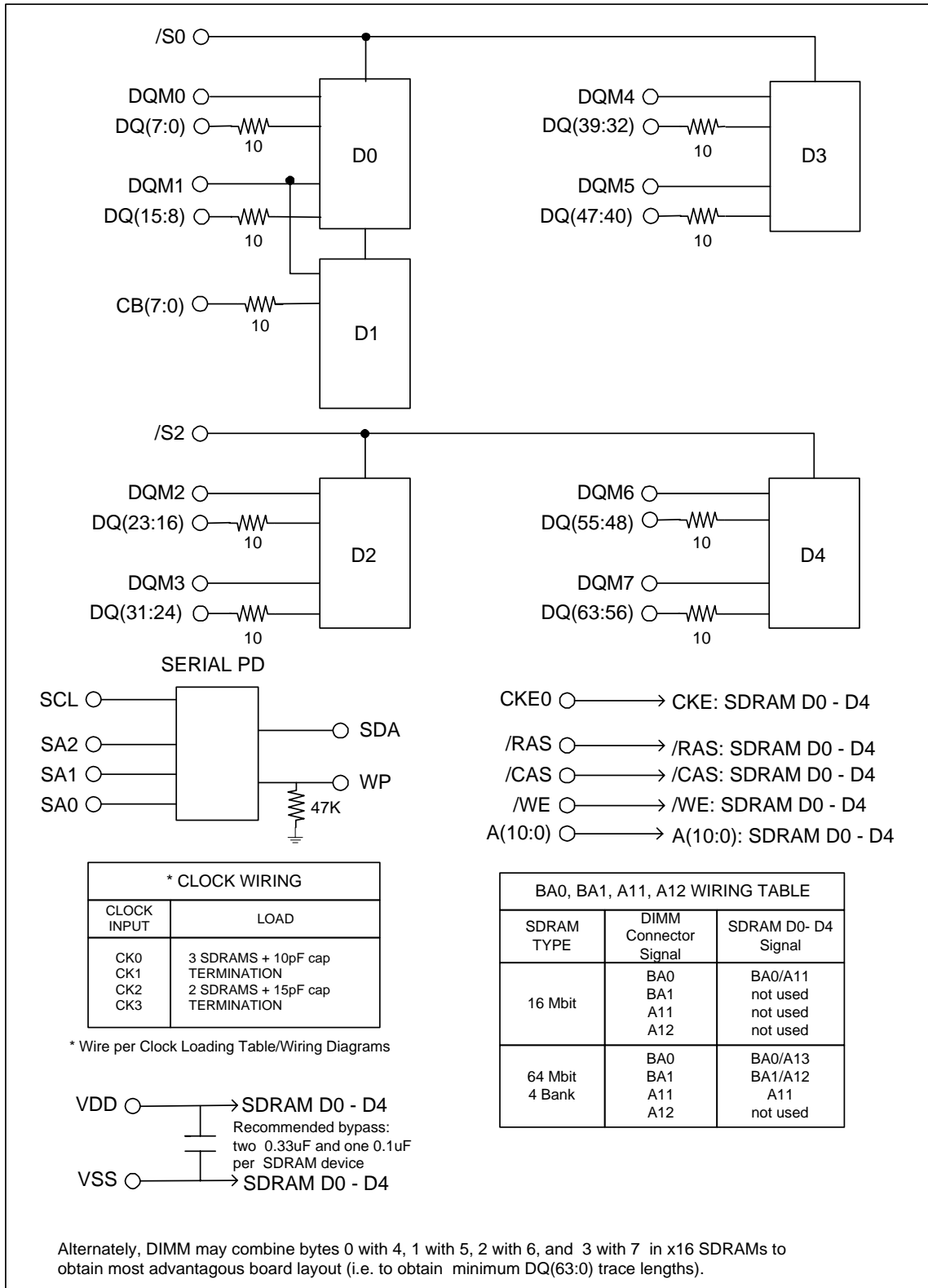


Figure 14: 72-Bit ECC SDRAM DIMM Block Diagram (1 row x16 SDRAMs)

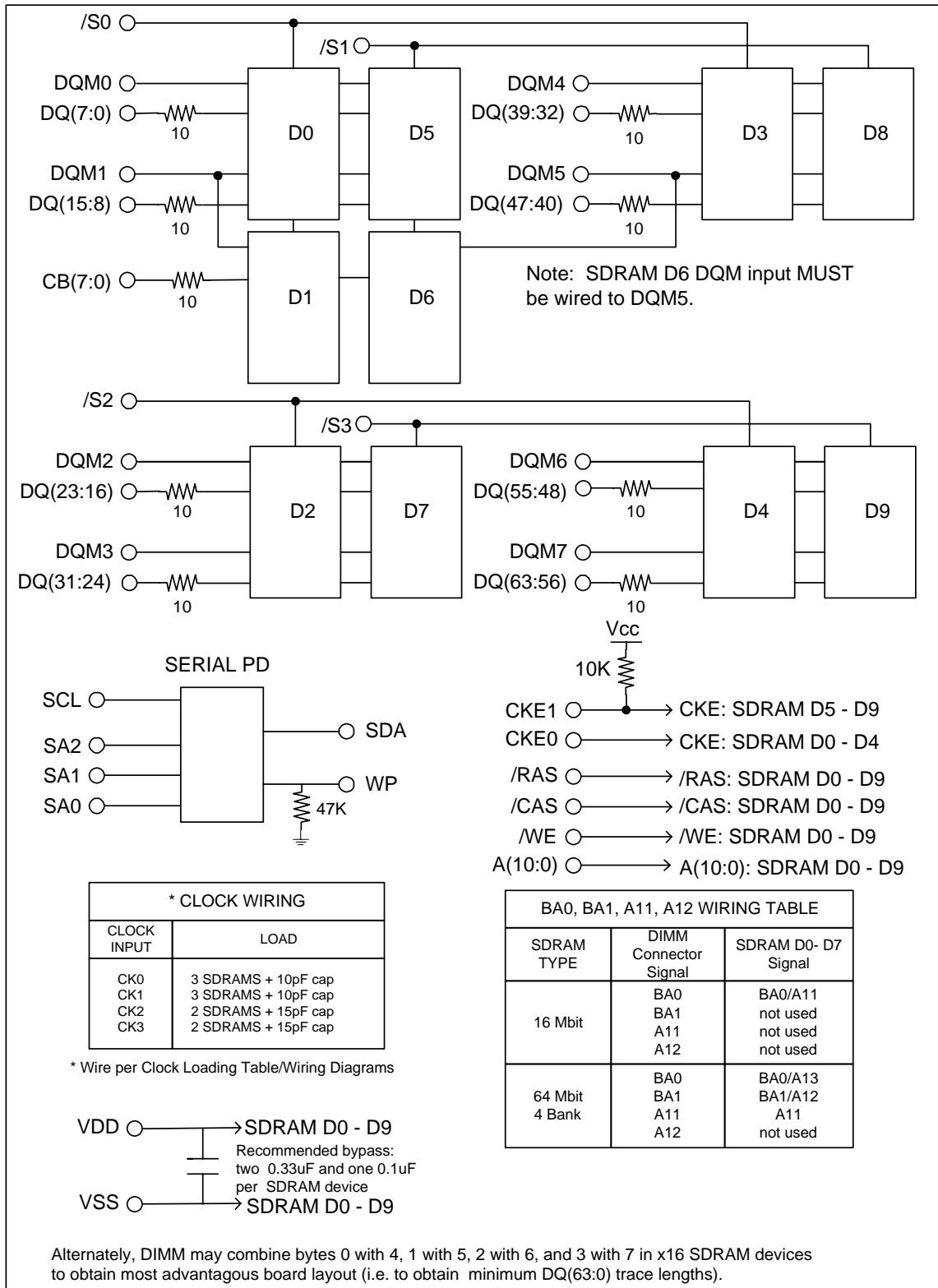


Figure 15: 72-Bit ECC SDRAM DIMM Block Diagram (2 rows x16 SDRAMs)

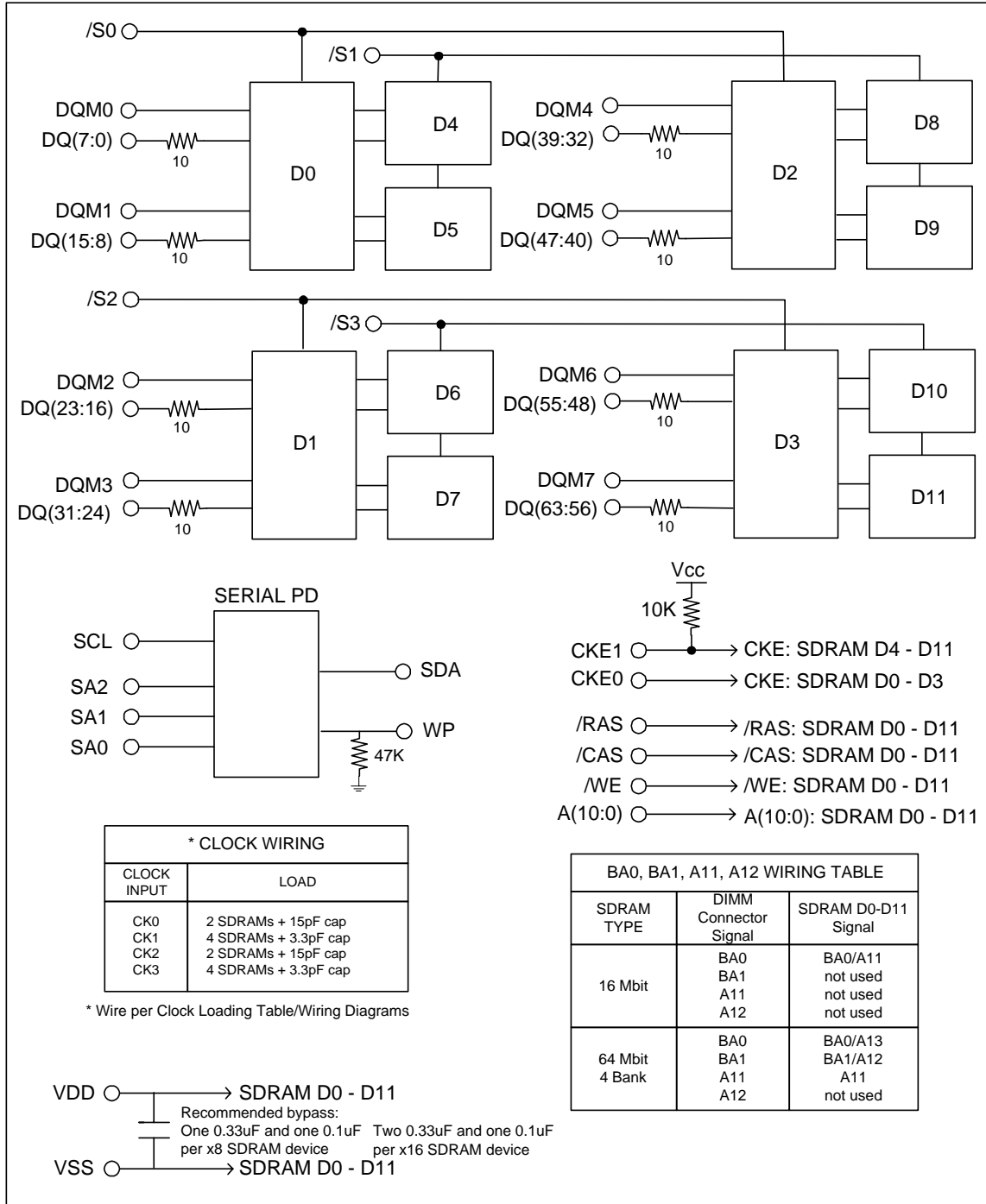


Figure 16: 64-bit non-ECC DIMM Block Diagram (1 Row x16 + 1 Row x8 SDRAMs)

- Note: Modules constructed using mixed configurations of x8 and x16 SDRAMs are still under investigation. Additional information will be released when it becomes available.
- Note: Mixed Mode modules must be designed so that if one type of SDRAM being used is higher than the other, the higher density SDRAMs must be placed on the primary side and connected to the primary side signals.

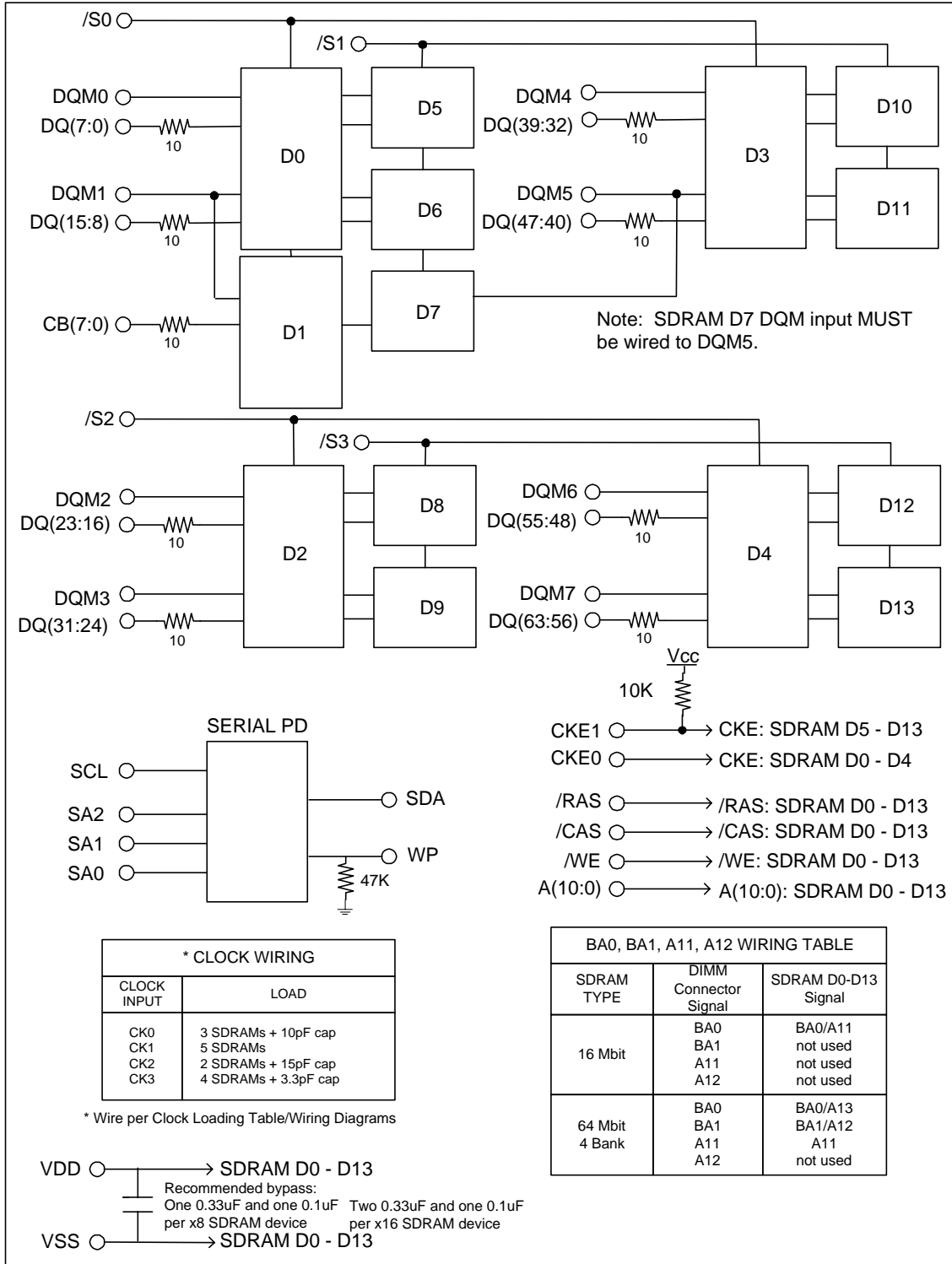


Figure 17: 72-Bit ECC SDRAM DIMM Block Diagram (1 Row x16 + 1 Row x8)

- Note: Modules constructed using mixed configurations of x8 and x16 SDRAMs are still under investigation. Additional information will be released when it becomes available.
- Note: Mixed Mode modules must be designed so that if one type of SDRAM being used is higher than the other, the higher density SDRAMs must be placed on the primary side and connected to the primary side signals.

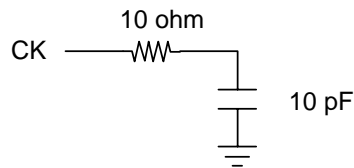
Clock Loading Table:

SDRAM Data Width	# of Rows on DIMM	Total # of SDRAMs	CLK Loading			
			CK0	CK1	CK2	CK3
x8	1	8	4 + 3.3pF cap	*	4 + 3.3pF cap	*
x8	2	16	4 + 3.3pF cap	4 + 3.3pF cap	4 + 3.3pF cap	4 + 3.3pF cap
x16	1	4	2 + 15pF cap	*	2 + 15pF cap	*
x16	2	8	2 + 15pF cap	2 + 15pF cap	2 + 15pF cap	2 + 15pF cap
x32	1	2	2 + 15pF cap	*	*	*
x32	2	4	2 + 15pF cap	2 + 15pF cap	*	*
x8	1	9	5	*	4 + 3.3pF cap	*
x8	2	18	5	5	4 + 3.3pF cap	4 + 3.3pF cap
x16	1	5	3 + 10pF cap	*	2 + 15pF cap	*
x16	2	10	3 + 10pF cap	3 + 10pF cap	2 + 15pF cap	2 + 15pF cap
x8 / x16	2	12	2 + 15pF cap	4 + 3.3pF cap	2 + 15pF cap	4 + 3.3pF cap
x8 / x16	2	14	3 + 10pF cap	5	2 + 15pF cap	4 + 3.3pF cap

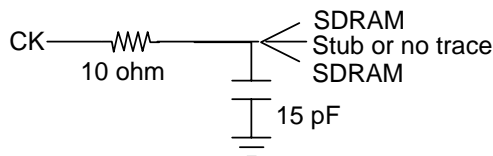
NOTE: ALL CAPS USED IN THE CLOCK NETS MUST HAVE A TOLERANCE OF +/- 5%

* Use termination R/C

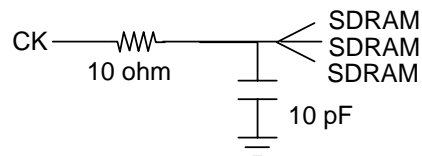
Termination R/C for CK signals not connected to SDRAMs:



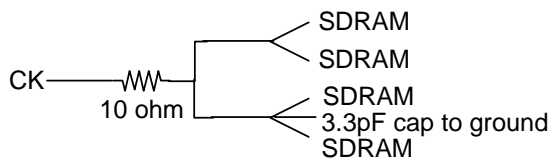
2 Load + 15pF cap CK nets:



3 Load + 10pF cap CK nets:



4 Load + 3.3pF CK nets:



5 Load CK nets:

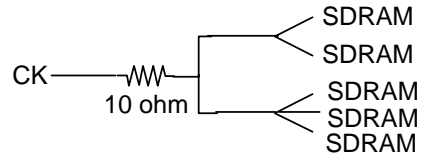


Figure 18: Clock Loading Table & Wiring Diagram

6.0 DIMM PCB Layout and Signal Routing

Printed Circuit Board

The DIMM printed circuit board may be of four or six layer design using glass epoxy material. (Please note that for a four layer design no information is currently available in this specification for the required lengths of clock traces routed on the outer layers. Such information is yet to be determined.) PCBs must have both a full ground plane layer and full power plane layer. The PCB stackup must be designed to achieve the following calculated board characteristics (assuming 6 mil wide traces) (see example below):

Table 8: PCB Calculated Parameters

Parameter	Min	Max
Propagation delay: S_0 [ns/ft] (outer layers)	1.6	2.0
Propagation delay: S_0 [ns/ft] (inner layers)	2.0	2.2
Trace impedance: Z_0 [Ω] (all layers)	60	80

Required Dielectric: 4.2 to 4.8

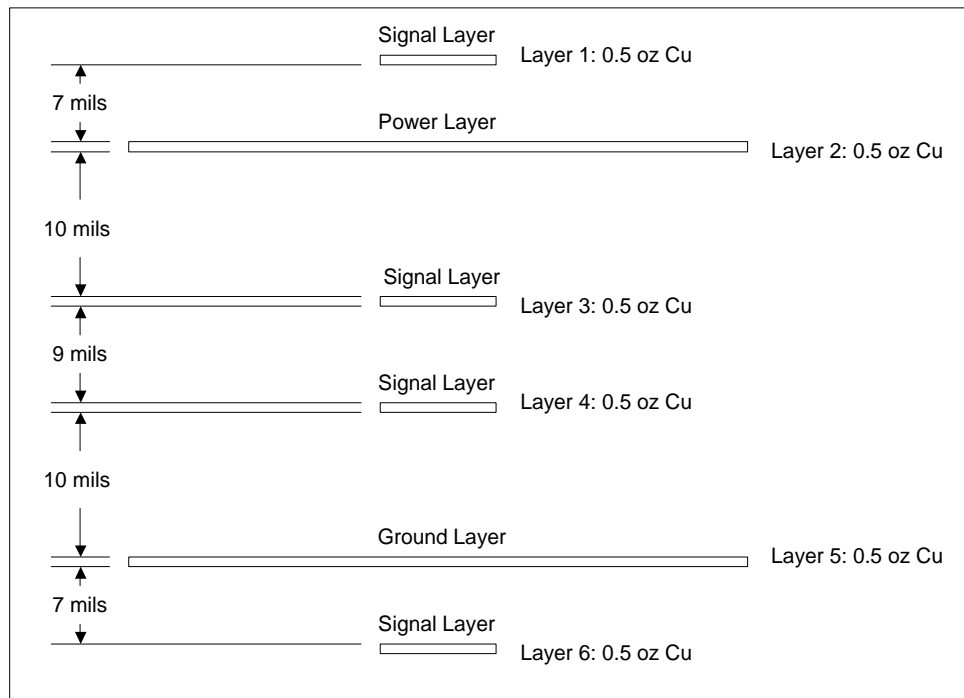


Figure 19: Example 6-layer PCB Stackup

Edge Connection

The PCB edge connector contacts shall be gold plated per Figure 5 note 10. Note: The PCB connector edge will not be chamfered.

EMI Reduction

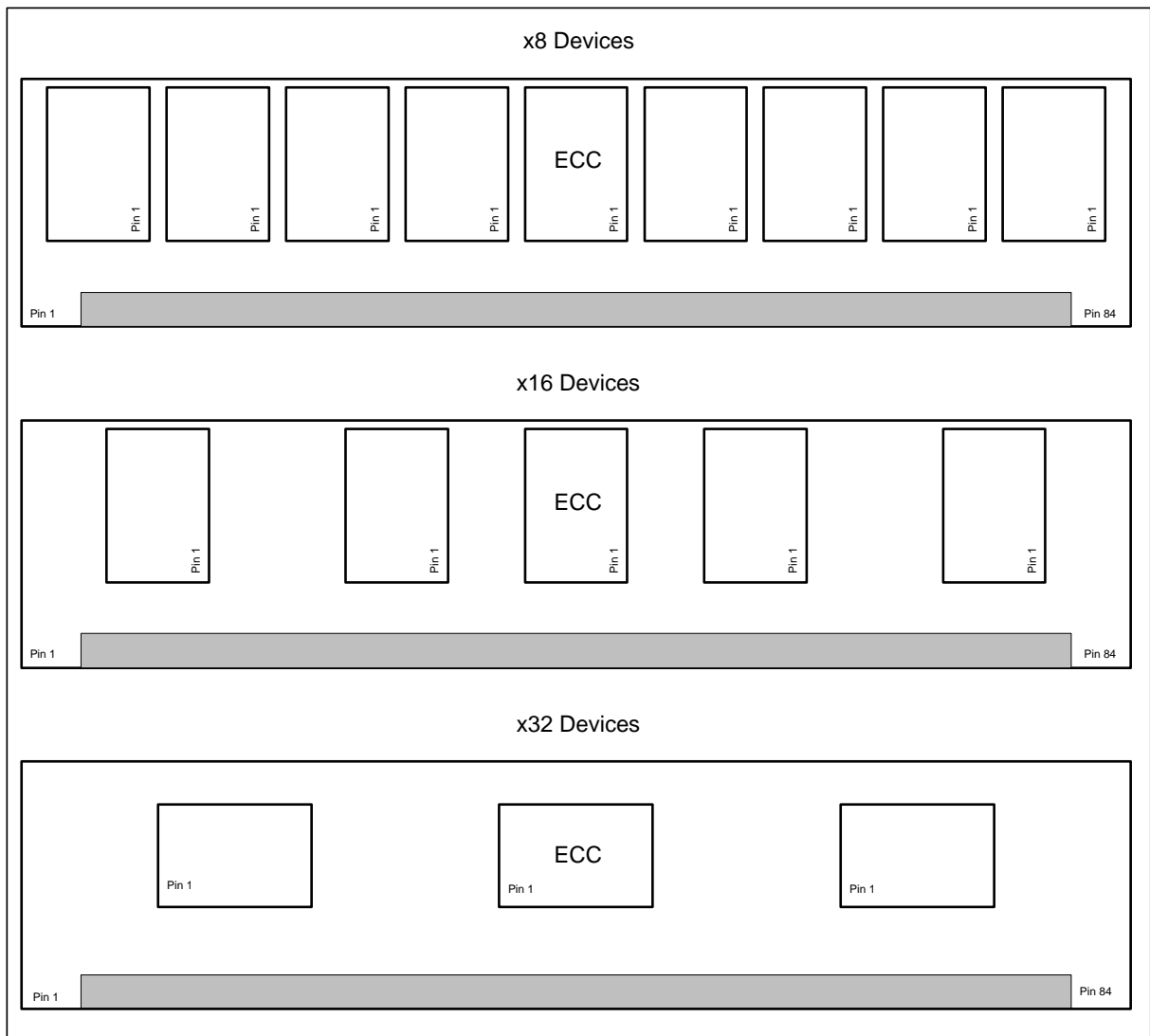
To minimize radiation from clock traces on the DIMMs, the following requirements should be adhered to:

- Any DIMM which makes use of all four clocks, should be routed as a six layer design with at least 90% of clock trace length routed in the inner signal layers.
(where the stackup is S-P-S-S-G-S)
- Both internal signal layers and the power plane should have a ground ring routed around the perimeter of the board and stitched to ground at intervals $<0.7''$. The ground rings should be 20 mils wide where space permits, but may be less in areas where it cannot be accommodated.

Component Types and Placement

Components shall be of surface mount type, and may be mounted on one or both sides of the PCB. Components shall be positioned on the PCB to meet the min and max trace lengths required for SDRAM data signals. Bypass capacitors for SDRAM devices must be located as near as practical to the device power pins. It is also important to place each SDRAM in the optimum position to ensure meeting of trace length and topology requirements. Pin swapping of data pins within individual bytes should also be used for the same reason.

The following diagram illustrates the suggested placement for x8, x16 and x32 SDRAM devices. For double-sided, non mixed-mode DIMMs, the back side placement should be mirrored from the front side. For mixed-mode DIMMs, the front side x8 placement should be combined with the mirrored back-side x16 placement. The placement for non ECC DIMMs is equivalent to the placements shown below after removing the ECC chips. It is intended that the space for ECC remain intact so that one layout may be used for both ECC and non-ECC cases; however, this is not a requirement. Exact spacing numbers are not provided, but are left up to the DIMM manufacturer to determine based on manufacturing constraints and signal routing constraints imposed by this specification.



Note: Modules constructed using x 32 bit SDRAMs are still under investigation. Additional information will be released when it becomes available.

Signal Groups

In this specification, the SDRAM timing-critical signals have been categorized into seven groups. The signals are divided into groups whose members have identical loading and routing topologies. The following table summarizes the signal groups by listing the signals contained in each. The following sections will describe routing restrictions associated with each signal group.

Table 9: Signal Topology Categories

SIGNAL GROUP	SIGNALS IN GROUP
Clock	CK [3:0]
Data	DQ [63:0] CB [7:0]
Data Mask (1/2 loads)	DQMB [0,2-4,6,7]
Data Mask (1/2/3 loads)	DQMB [1,5]
Chip Select	CS# [3:0]
Clock Enable	CKE# [0,1]
Double cycle signals	A [12:0] BA [0,1] RAS# CAS# WE#

Signal Topology and Length Restrictions

In order to meet signal quality and setup/hold time requirements for the memory interface, certain routing topologies and trace length requirements must be met. The signal topology requirements are shown pictorially in the following pages. Each topology diagram is accompanied by a trace length table that lists either the minimum and maximum lengths allowed for each trace segment or the min and max lengths for the entire net. Each diagram also shows where vias are allowed or includes a note that specifies where vias are allowed that are not shown in the diagram.

Routing Rules

General Info: All signal traces except clocks are routed using 6/10 rules.
(6 mil traces and 10 mil minimum spacing between adjacent traces).

Clocks should be done in 6 mil trace width and 12 mil minimum spacing.

Clocks must be routed with at least 90% of the total trace length in the inner layers.

No test points are required.

Topology Diagram Explanation and Examples

The routing topology diagrams in this section are intended to be used to determine individual signal topologies on a DIMM for any supported configuration. The primary differences in topologies result from using different SDRAM data widths and the choice of whether or not to use ECC.

The way that these diagrams should be read is the following:

Only the cylinders labeled with length designators represent actual physical trace segments. All other lines should be considered zero in length.

All loads and traces outside of the dashed boxes constitute the base topology which covers the minimum loading case for each signal.

Allowed vias are either shown as circles on the topology diagrams or are otherwise documented under each diagram in a separate note.

The topology for a given configuration can be determined by adding the traces and loads within the dashed boxes to the base topology. Add only the traces and loads within boxes that apply for the desired configuration.

Please see the following page for an example of how to use the topology diagrams.

Example: For an 8Mb, single-sided, non-ECC DIMM that uses 16Mbit 1Mx16 SDRAM devices, the resulting topology for M_Ax, B_Ax, RAS#, CAS# and WE# would be the following:

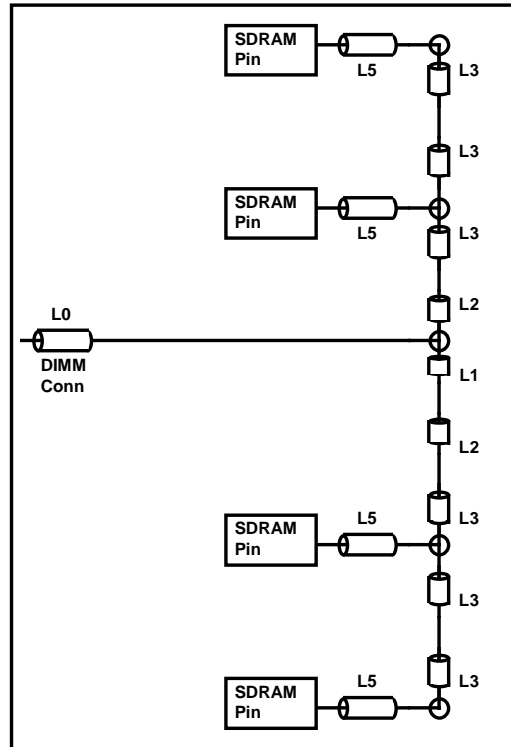


Figure 20: Example Topology

Once the topology has been determined, the permitted segment length ranges for that topology can be read from the table below each topology diagram. It is important to note that some configurations will require more than one topology to account for different numbers of loads on copies of the same signal.

Topology for Clock: CK[3:0]

Special attention must be given to the routing of the SDRAM clock signal(s) to ensure adequate signal quality, rise/fall time, minimum skew between clock edges at each SDRAM component, and predictable skew to motherboard chipset clocks. For that reason, all clocks are made to look electrically like the worst case load (5 loads). Clock signals must have either five SDRAM loads, four SDRAM loads plus an extra 3.3pF cap load or two or three loads plus an extra cap (value depends on x16 or x32 and whether or not ECC is installed on the net). All unused clocks should be terminated into 10 ohms and 10 pF.

DIMMs using all four clocks must have the clocks routed with at least 90% trace length in the inner layers.

DIMMs using only two clocks may be routed on the outer layers, but the associated trace lengths will be different. As of this spec revision, the outer layer clock trace lengths are yet to be determined. Clock traces must be 6 mils wide with 12 mil spacing to any other signal including the clocks themselves. The following figure illustrates the recommended clock topologies, and the table on the following page lists required trace segment lengths and added capacitance values and tolerances.

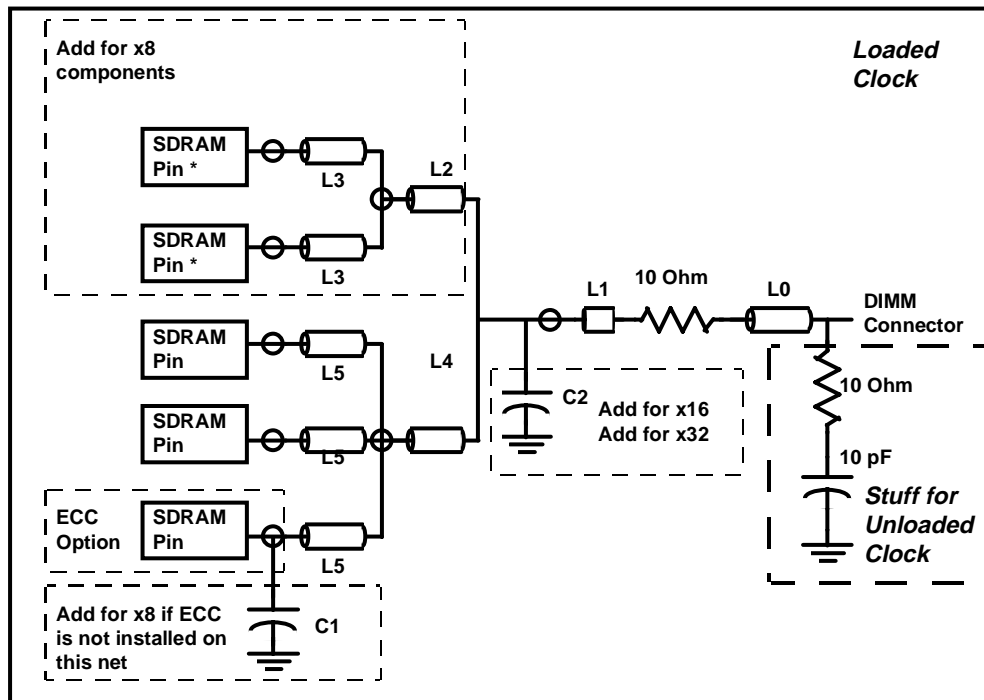


Figure 21: Signal routing topologies for Clocks

Note: The L0 trace segment may contain two vias which are not shown in this diagram. Those vias should be placed near the edge connector and resistor respectively. The L2, L3, L4 and L5 trace segments may each contain one via which is not shown in the diagram.

Table 10: Trace Length Table for Clock Topologies

Comp Width	Route Layer	SDRAM loads	L0	L1	L2	L3	L4	L5	C1	C2
x32	Outer	2 or 3	0.5	0.11	N/A	N/A	1.6	3.0	N/A	10pF/15pF
x16	Outer	2 or 3	0.5	0.11	N/A	N/A	1.6	3.0	N/A	10pF/15pF
x32	Inner	2 or 3	0.5	0.11	N/A	N/A	1.2	1.3	N/A	10pF/15pF
x16	Inner	2 or 3	0.5	0.11	N/A	N/A	1.2	1.3	N/A	10pF/15pF
x8	Inner	4 or 5	1.25	0.06	1.20	0.66	0.60	0.66	3.3pF	N/A

1 All distances are given in inches and should be kept within a tolerance of +/- 0.01 inches

2 All capacitances are given in picoFarads and should be kept within a tolerance of +/- 5%

Defining clock trace lengths

The clock trace lengths and topologies were defined based on simulations using the values in Tables 8 and 10 of this document as well as the following assumptions:

Motherboard impedance: 60 to 80 ohms

Motherboard trace length: 3 inches

Series termination at source: 22ohms

Connector modeled as transmission line: 0.25 to 0.6 inch, 60 to 80 ohms, 2ns/ft

Threshold voltage: 1.5v

SDRAM clock input characteristics from current Intel PC SDRAM Specification

Target flight time from source to load: 2.14nsec +/-0.41nsec (not including buffer pin to pin skew)

If simulations are done to determine clock lengths for unspecified cases, these assumptions should be used. Clock buffer models for simulation should be acquired from vendors of 66/100 MHz clock components intended for use with PC SDRAM DIMMs. Intel does not guarantee the correctness of any vendor's clock buffer models, and it is recommended that several different vendor's models are used to simulate. Also, as a minimum, four corner cases should be simulated for 1) fast motherboard/ fast DIMM; 2) slow motherboard/slow DIMM; 3) fast motherboard/slow DIMM; 4) slow motherboard/fast DIMM. These cases consist of varying buffer strength, trace impedance, propagation velocity, and loading.

Topology for Data: DQ[63:0] & CB[7:0]

These signals are routed using a balanced “T” topology on any layer. The table defines the line length ranges allowed for these signals. For the purpose of specifying trace segment lengths, the data lines have been broken down into two subcategories based on the location of their edge connector pins. These two data “zones” have lengths specified that make the data lines connecting toward the outside edge shorter in min and max length. This is done to allow the opportunity to pair the necessarily longer data line traces on the motherboard with traces that can be made shorter on the DIMMs, and the necessarily longer DIMM traces with the potentially shorter traces on the motherboard.

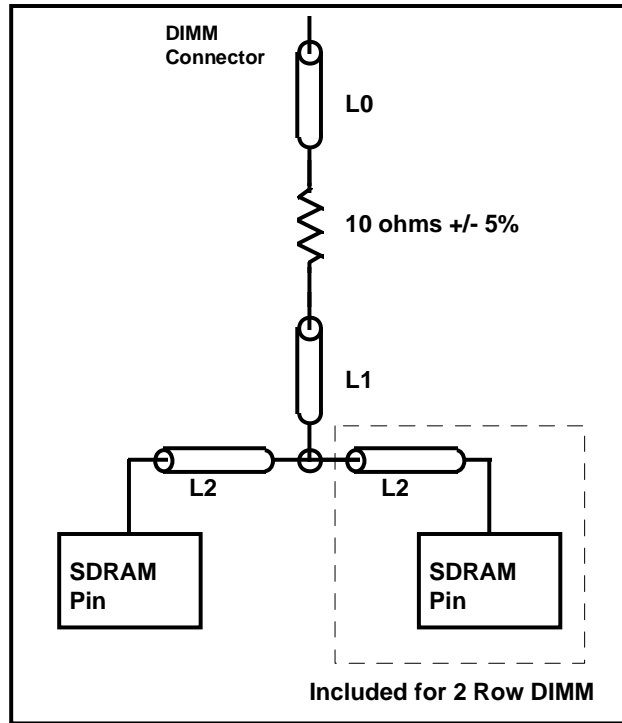


Figure 22: Signal routing topologies for Data

Note: The L0 and L1 trace segments together may contain up to 2 additional vias which are not shown in the diagram.

Data Zone I : DQ [63-56, 39-24, 7-0]

Data Zone II : DQ [55-40, 23-8] ; CB [7-0]

Table 11: Trace Length Table for Data Topologies

Comp Width	# of loads	Zone	L0 Min	L0 Max	L1 Min	L1 Max	L2 Min	L2 Max	Total Min	Total Max
ALL	1/2	I	0.10	0.80	0.10	0.80	0.05	0.15	0.9	1.0
ALL	1/2	II	0.10	1.00	0.10	1.00	0.05	0.15	1.0	1.4

- 1 All distances are given in inches
- 2 Total Min and Total Max refer to the min and max respectively of L0 + L1 + L2. Also, the total min and max limits are tighter than the sum of the individual min and max lengths. This implies that not all individual segment lengths may be adjusted to the min or max value respectively at the same time.

Topology for Data Mask (1/2 Loads): DQMB[7,6,4-2,0]

These signals are routed using a “Y” topology on any layer. The tables define the line length ranges allowed for these signals.

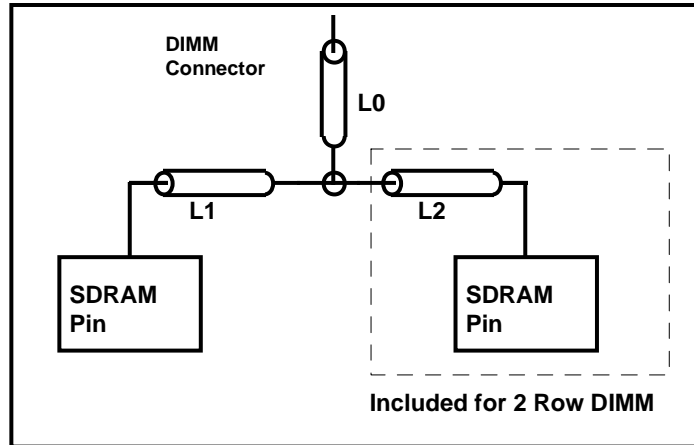


Figure 23: Signal routing topologies for Data Mask (1/2 Loads)

Note: The L0, L1 and L2 trace segments may each contain 1 additional via which is not shown in the diagram.

Table 12: Trace Length Table for Data Mask Topologies (1/2 Loads)

Comp Width	# loads	L0 Min	L0 Max	L1 Min	L1 Max	L2 Min	L2 Max
ALL	1/2	2.00	2.15	0.24	0.30	0.24	0.30

¹ All distances are given in inches

Topology for Data Mask (1/2/3 Loads): DQMB[5,1]

These signals are routed using a star topology on any layer. The tables define the line length ranges allowed for these signals.

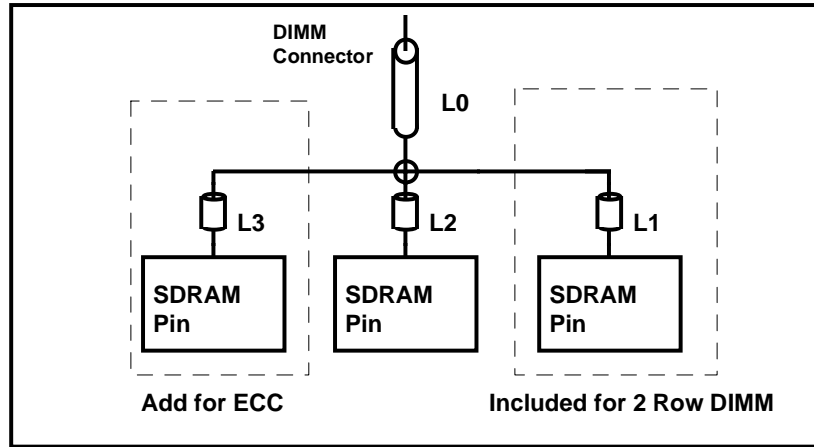


Figure 24: Signal routing topologies for Data Mask (1/2/3 Loads)

Note: The L0, L1, L2 and L3 traces may contain up to 1 additional via each which is not shown in the diagram.

Table 13: Trace Length Table for Data Mask Topologies (1/2/3 Loads)

Comp Width	# loads	L0 Min	L0 Max	L1 Min	L1 Max	L2 Min	L2 Max	L3 Min	L3 Max
ALL	1/2/3	0.90	1.00	0.63	0.65	0.63	0.65	0.63	0.65

¹ All distances are given in inches

Topology for Chip Select: CS#[3:0]

This signal is routed using a balanced “comb” topology on any layer. The table below defines the line length ranges allowed for these signals. Diagrams are shown for both cases of a net with an ECC device (or the stuffing option for one) and of a net that does not have an ECC stuffing option.

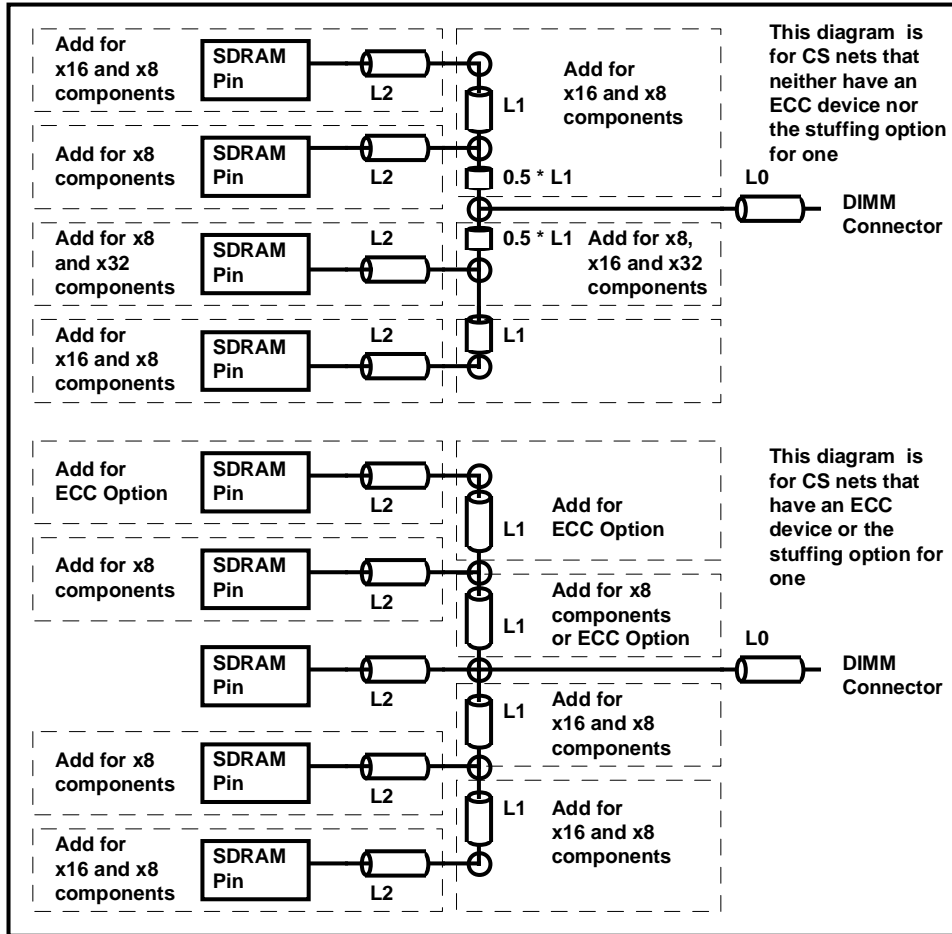


Figure 25: Signal routing topologies for Chip Select

Note: The L0 trace may contain up to 2 vias which are not shown in the diagram. Those vias may be placed anywhere along that trace.

Table 14: Trace Length Table for Chip Select Topologies

Comp Width	# of loads	L0 Min	L0 Max	L1 Min	L1 Max	L2 Min	L2 Max
x32	1/2	TBD	TBD	TBD	TBD	TBD	TBD
x16	2/3	1.30	1.65	0.50	0.60	0.06	0.08
x8	4/5	1.30	1.65	0.50	0.60	0.06	0.08

1 All distances are given in inches

Topology for Clock Enable: CKE#[1:0]

This signal is routed using a balanced “comb” topology on any layer. The table below defines the line length ranges allowed for each trace segment.

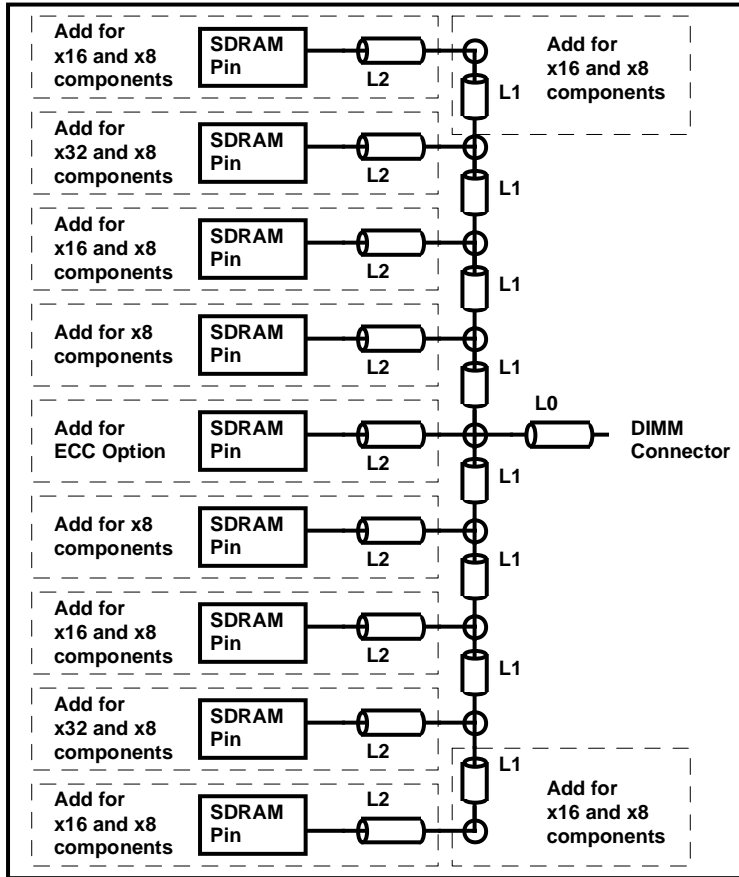


Figure 26: Signal routing topologies for Clock Enable

Note: The L0 trace may contain up to 2 vias which are not shown in the diagram. Those vias may be placed anywhere along that trace.

Table 15: Trace Length Tables for Clock Enable Topologies

Comp Width	L0 Min	L0 Max	L1 Min	L1 Max	L2 Min	L2 Max
ALL	1.40	1.45	0.50	0.60	0.060	0.085

1 All distances are given in inches

Double Cycle Signals: MAX, BAX, SRAS#, SCAS#, WE#

These signals are routed using a balanced, double-sided “comb” topology on any layer. The table below defines the line length ranges allowed for these signals.

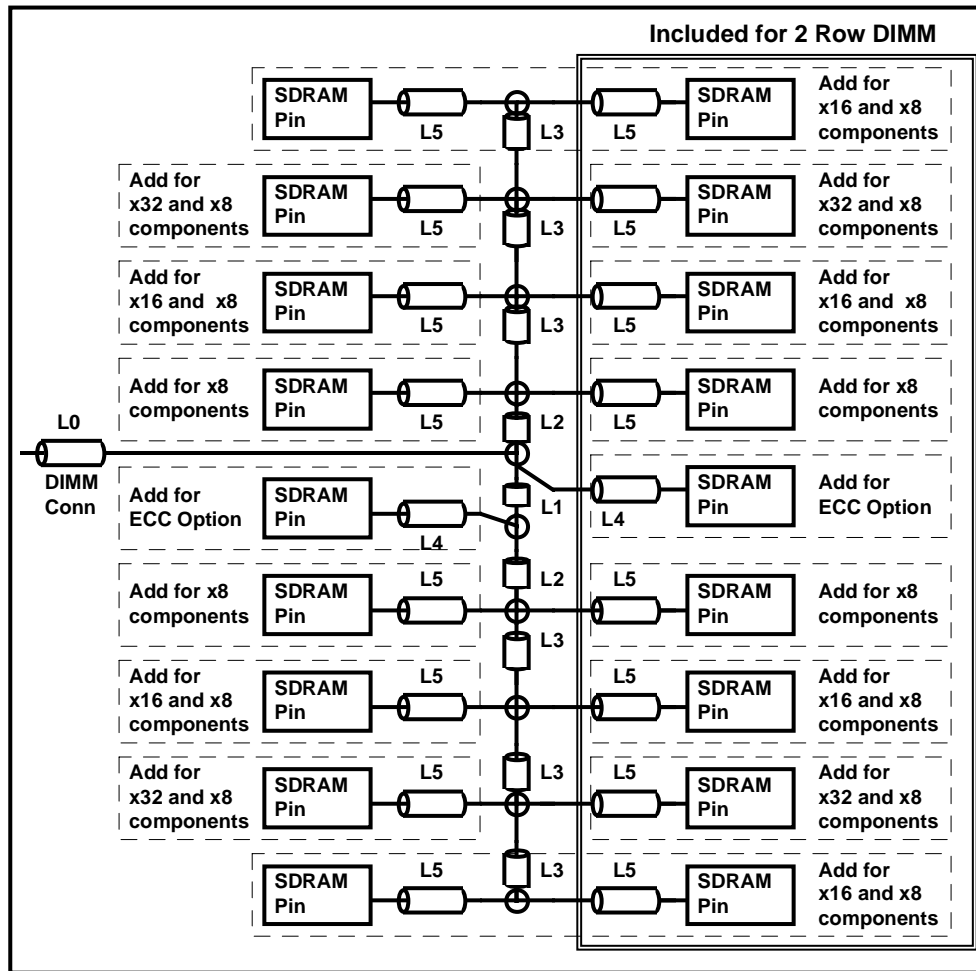


Figure 27: Signal routing topologies for Double Cycle Signals

Note: The L0 trace may contain up to 2 additional vias which are not shown in the diagram. Those vias may be placed anywhere along the trace segment.

Table 16: Trace Length Table for Double Cycle Signal Topologies

Comp Width	# loads	L0 Min	L0 Max	L1 Min	L1 Max	L2 Min	L2 Max	L3 Min	L3 Max	L4 Min	L4 Max	L5 Min	L5 Max
x32	2/3/4/6	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
x16	4/5/8/10	1.00	1.60	0.20	0.30	0.20	0.55	0.40	0.70	0.05	0.18	0.07	0.35
x8	8/9/16/18	1.00	1.60	0.20	0.30	0.20	0.55	0.40	0.70	0.05	0.18	0.07	0.35

1 All distances are given in inches

7.0 DIMM PCB and Final Assembly Labeling Requirements

Printed Circuit Board Labeling

The printed circuit board is required to have the following labeling contained in etch or silkscreen:

Flammability indicator (see Section 2 of this document, under Safety)

The text: PCSDRAM-REV#.#

(#.# corresponds to the revision of the PC SDRAM spec to which the PCB is designed)

Assembled DIMM Naming Convention

In order to be able to visually identify the critical parameters of a given DIMM, the following naming convention will be used.

On component or sticker on DIMM (supplier option):

- use minimum 8point font

PCX-abc-def

Where X=MHz

a = CL value

b = trcd value

c = trp value

d = tac value

e = spd rev #

f = reserved

Example: PC100-322-620

is 100MHz, CL3, trcd=2, trp=2, tac=6, 2= spd rev 1.2 with the last digit reserved.

Note: A two digit designator for both the tac and spd fields is optional if appropriate.

Example: PC100-322-60120

is also 100MHz, CL3, trcd=2, trp=2, tac=6, 12= spd rev 1.2 with the last digit reserved.

8.0 SDRAM Component Specifications

The SDRAM components used with this DIMM design spec MUST adhere to the most recent revision of the Intel "PC SDRAM Specification." Please reference to that document for all technical specifications and requirements of the SDRAM devices. Any violation of the requirements of the Intel PC SDRAM Component Specification constitutes a violation of the PC SDRAM Unbuffered DIMM Specification as well.

9.0 EEPROM Component Specifications

The Serial Presence Detect function MUST be implemented on the PC SDRAM DIMM. The component used and the data contents must adhere to the most recent version of the Intel "SDRAM Serial Presence



Detect Specification". Please reference to that document for all technical specifications and requirements of the serial presence detect devices. Any violation of the requirements of the Intel SDRAM Serial Presence Detect specification constitutes a violation of the PC SDRAM Unbuffered DIMM Specification as well.